



# Stability of irradiated LGAD sensors in the Fermilab high-rate proton beam facility

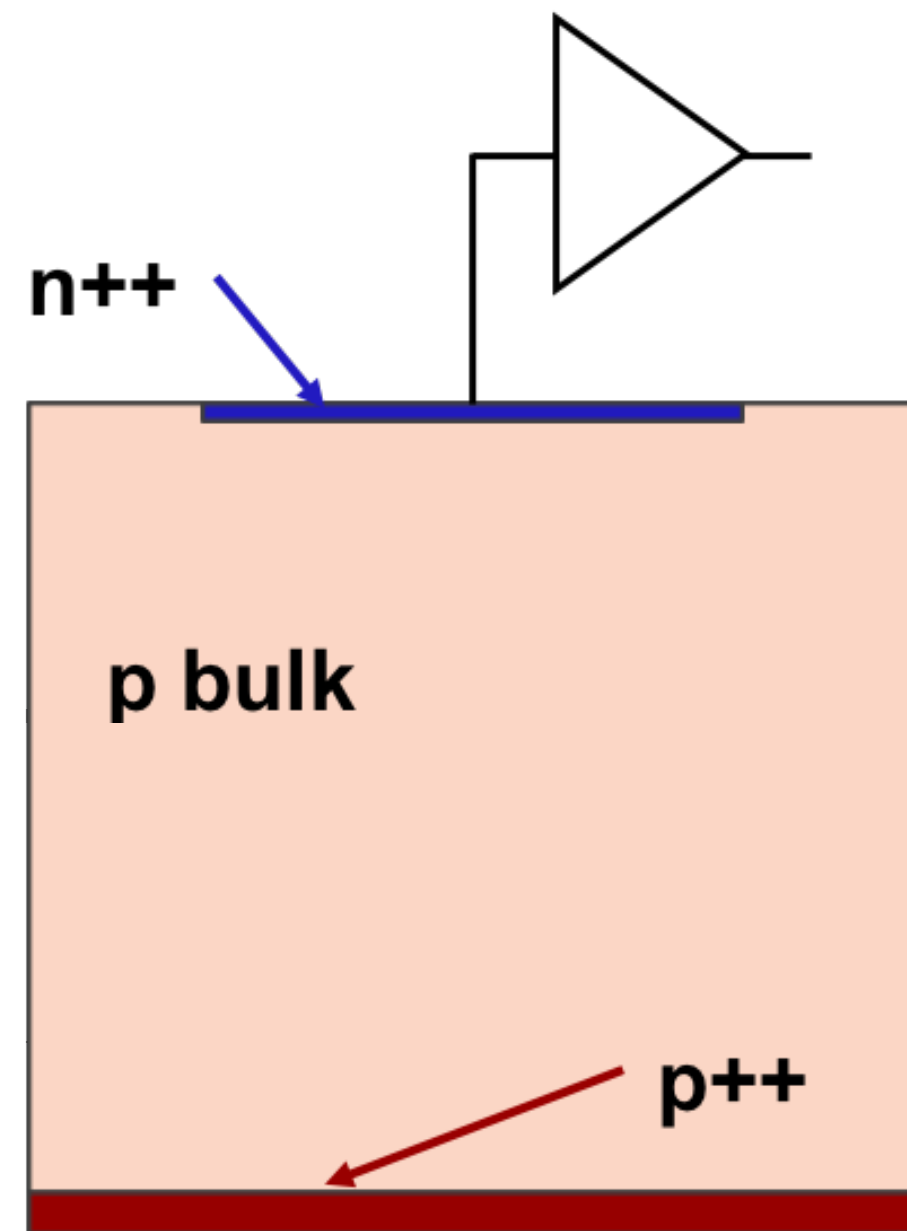
Ryan Heller for the CMS MIP Timing Detector Collaboration

10<sup>th</sup> Beam Telescope and Test Beam Workshop, Lecce, Italy

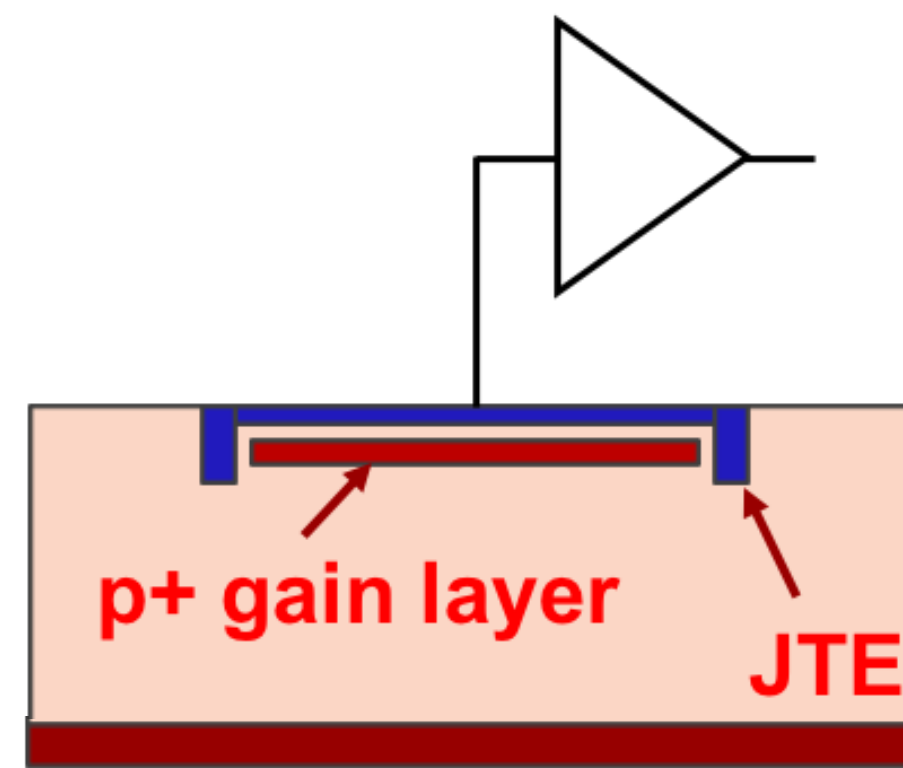
June 22nd, 2022

# Precision timing with LGADs

- Silicon sensors optimized for timing: Low Gain Avalanche Detectors (**LGADs**)
  - Thin depletion region (50 micron): fast & uniform signals
  - Internal gain: boost signal-to-noise (x10-30)



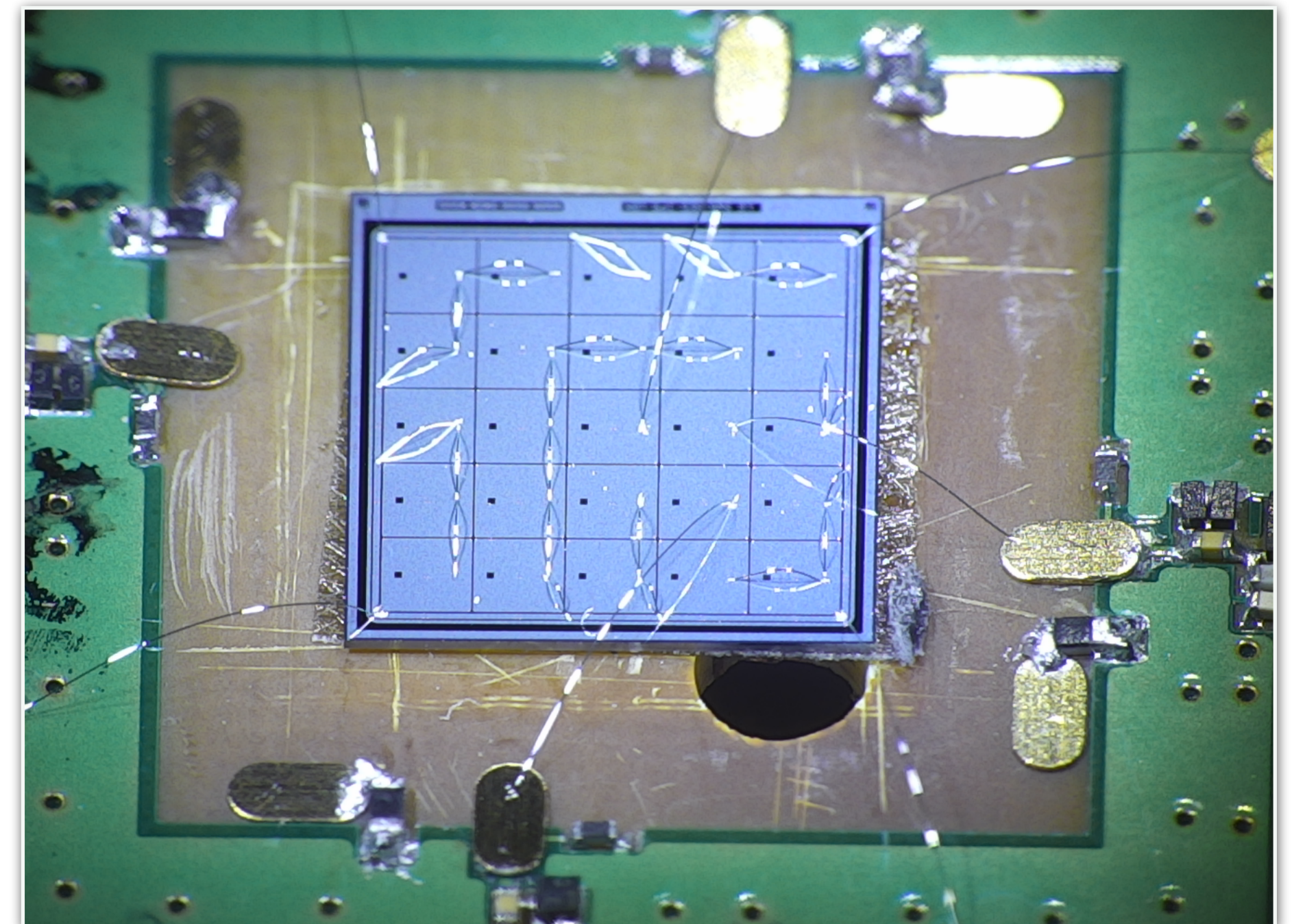
Traditional silicon detector



Low Gain Avalanche Detector

[arxiv:1704.08666](https://arxiv.org/abs/1704.08666)

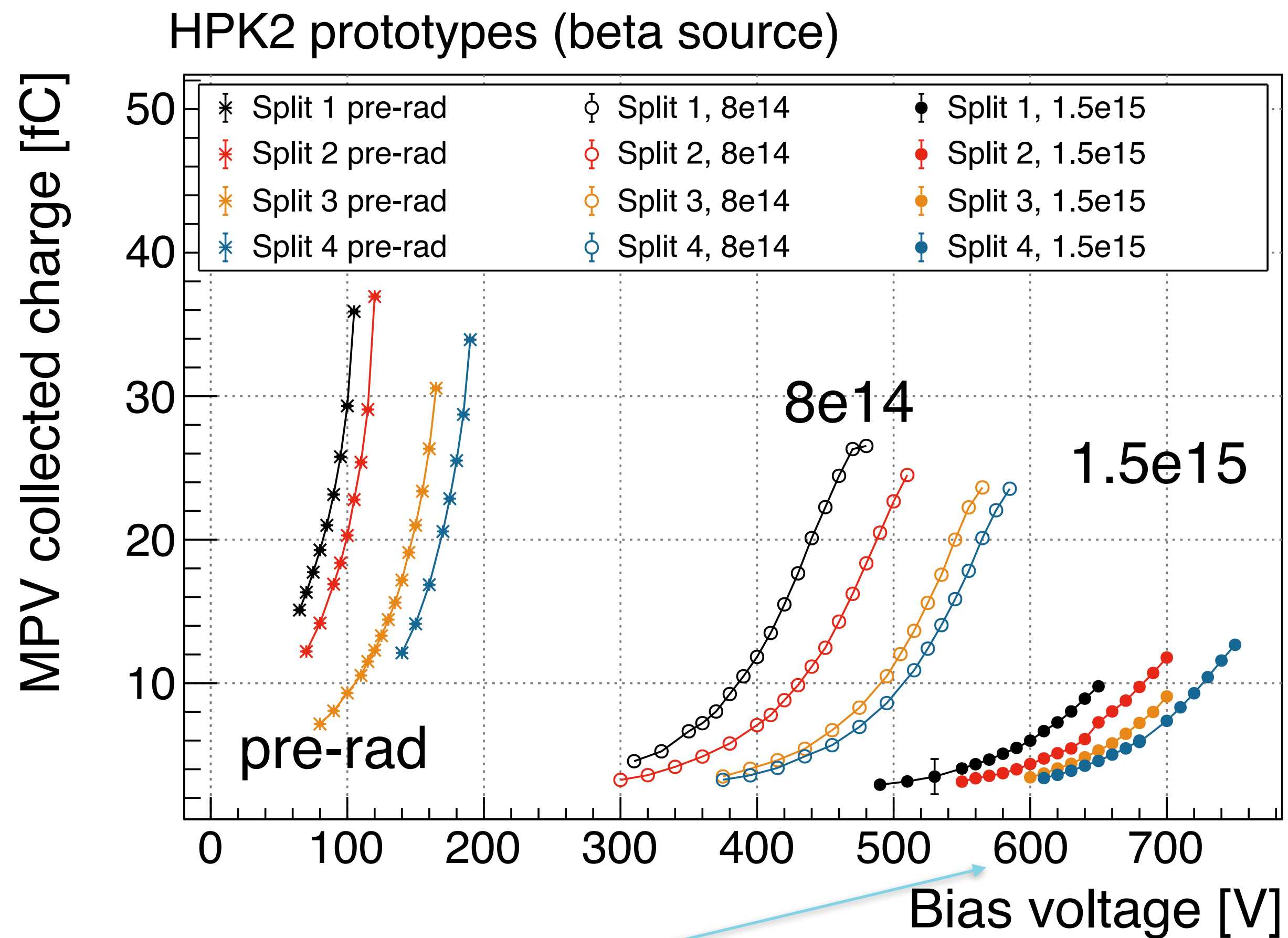
HPK LGAD prototype, 1.3 mm pads



- CMS Endcap Timing Layer: timestamp every track with 30-40 ps resolution!

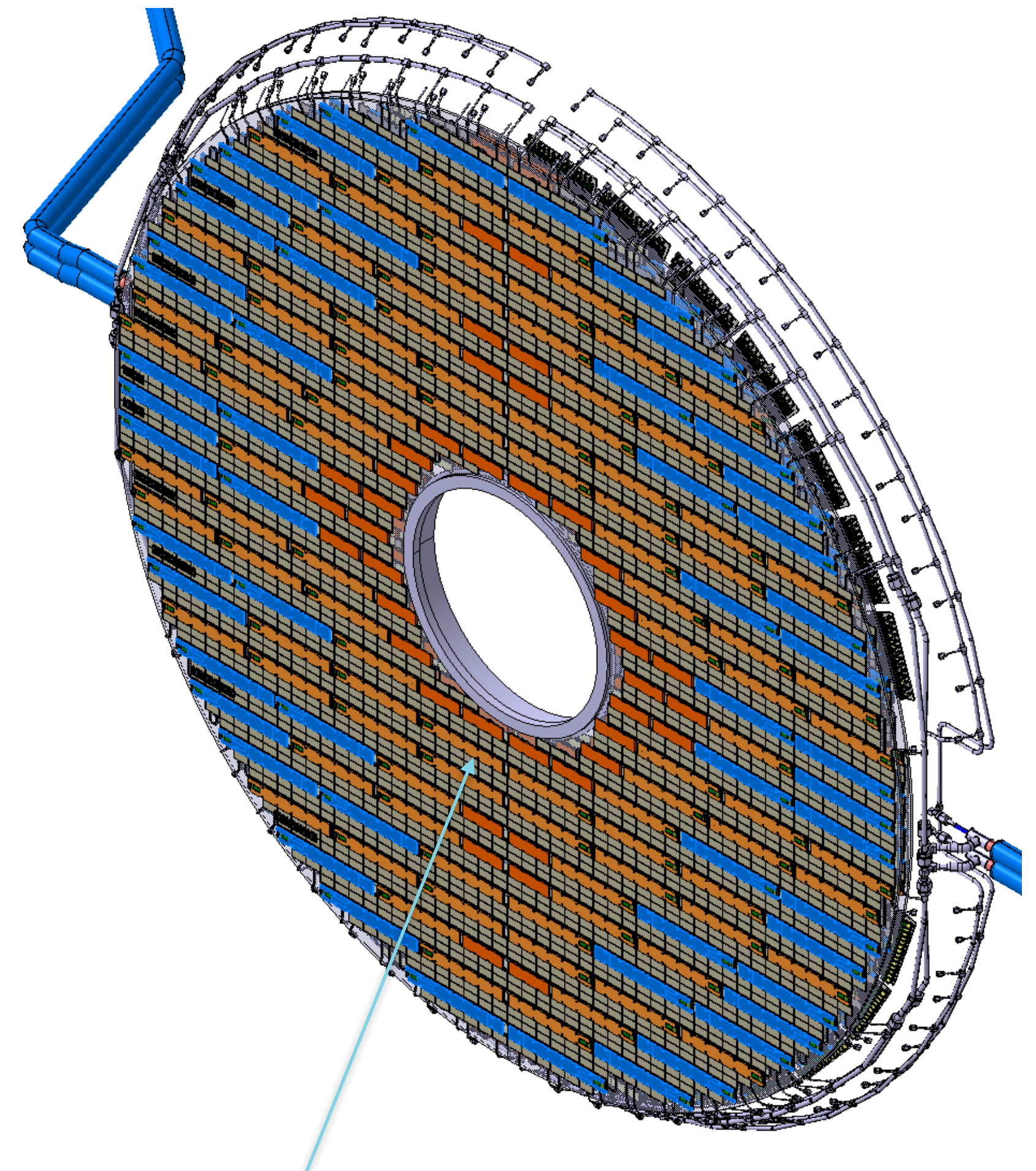
# LGADs under irradiation

- Gain layer de-activates with irradiation
- Increase bias voltage over time to maintain large signals.



Ultra high E-field: 12 V per micron!

## CMS Endcap Timing Layer (1 disk)

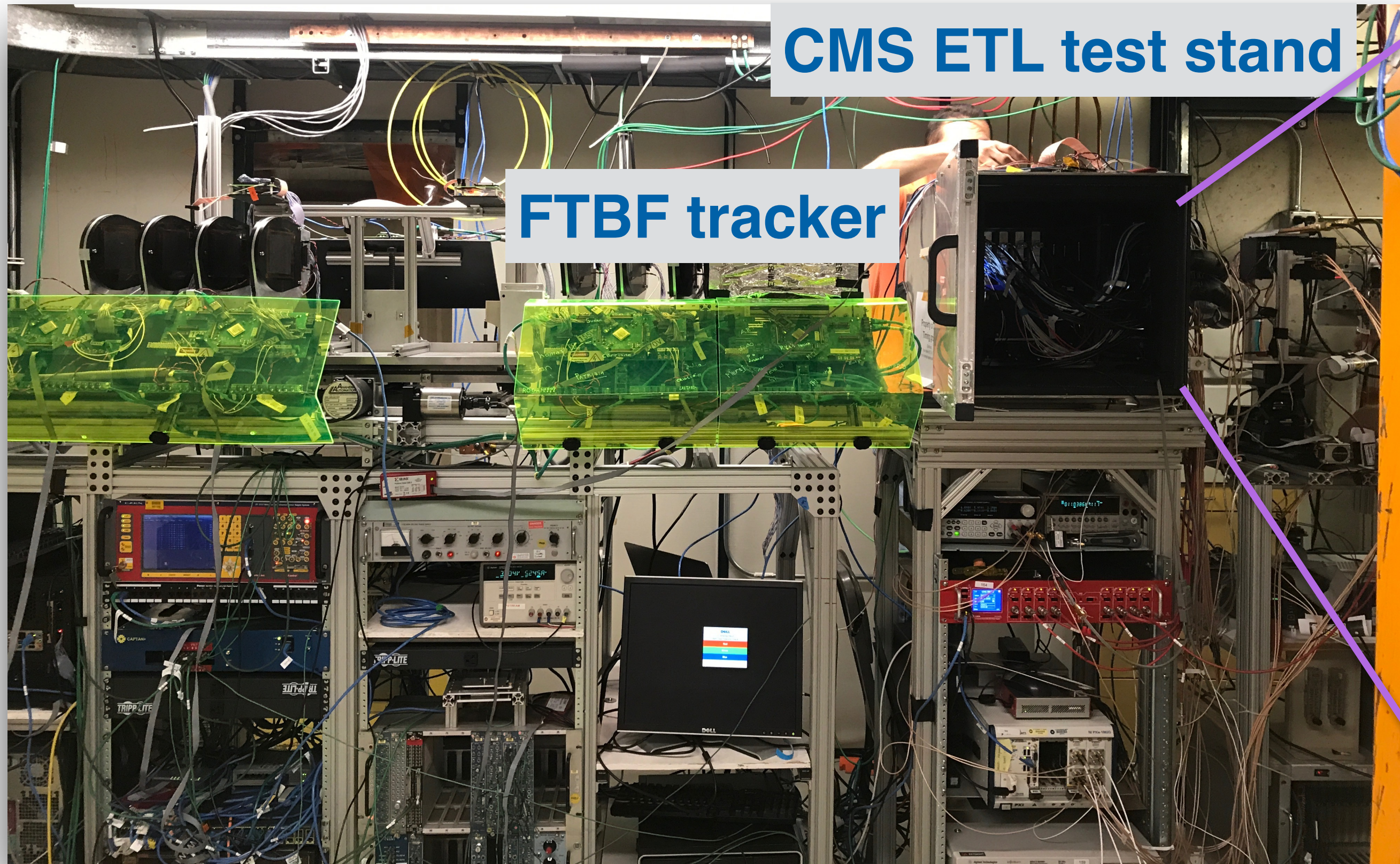


Inner radii: reach fluence of  $1.5 \times 10^{15}$  neq/cm<sup>2</sup>

# LGAD mortality

- Anecdotal evidence in past for death of highly irradiated LGADs at test beams, at very high field.
  - Historically, not clear if caused by environmental/mishandling issue, or intrinsic sensor failure mode.
- Several test beam campaigns at Fermilab dedicated to study of LGAD mortality
  - 30 sensors studied December 2020 - March 2021 → **understand death mechanism**
  - 20 sensors at extreme rate facility December 2021 → **demonstrate safe operation regions**
- Many key goals accomplished:
  - Refine understanding of cause of death
  - Collect statistics with diverse set of sensors
  - Test treatments to prevent mortality
  - Probe safe regions for operation and develop mitigation strategy.

# Mortality studies at Fermilab Test Beam Facility



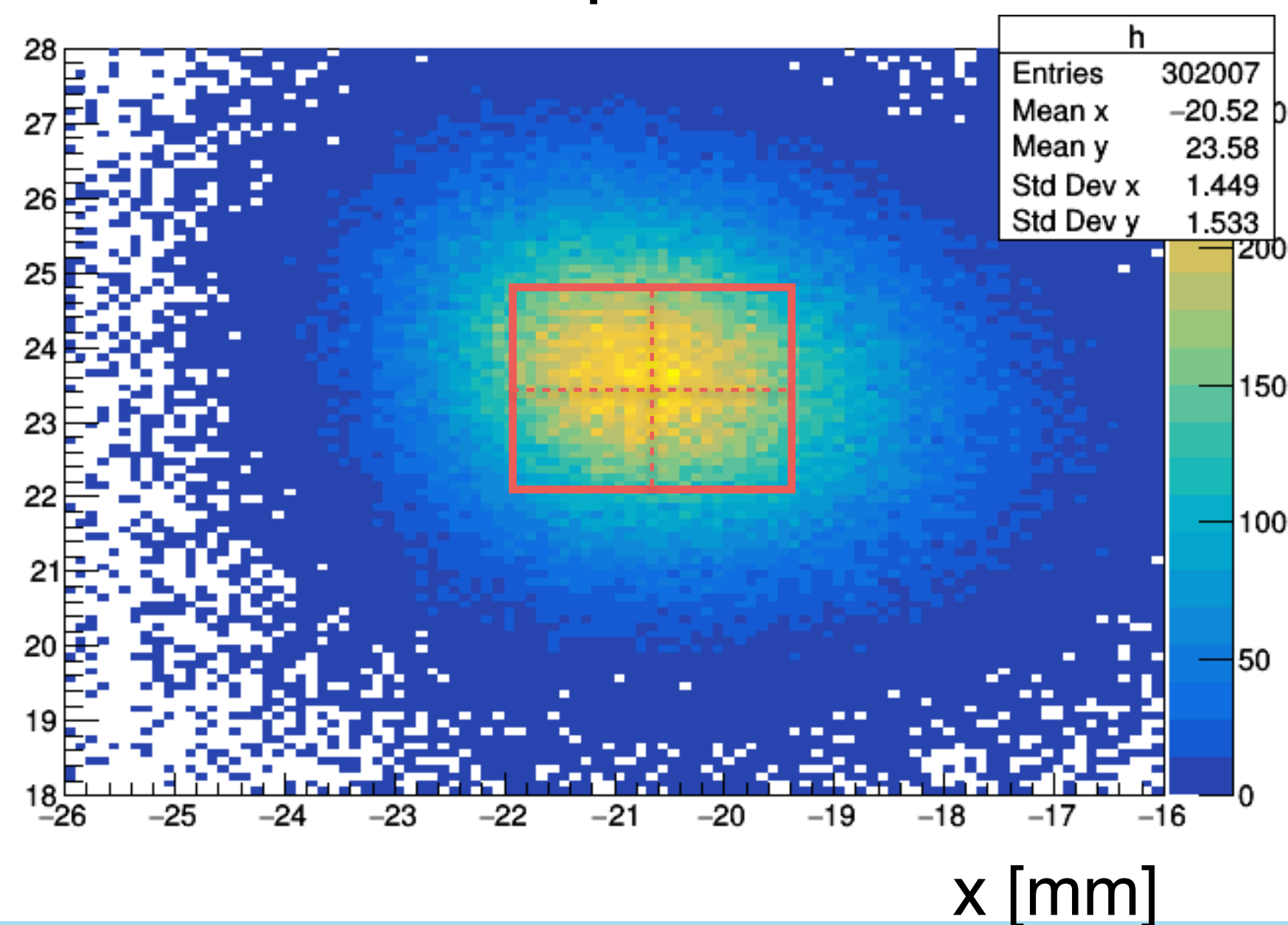
Is LGAD burnout caused by protons, or spontaneous?  
Impact of gain, bias voltage, irradiation ??

# Mortality studies

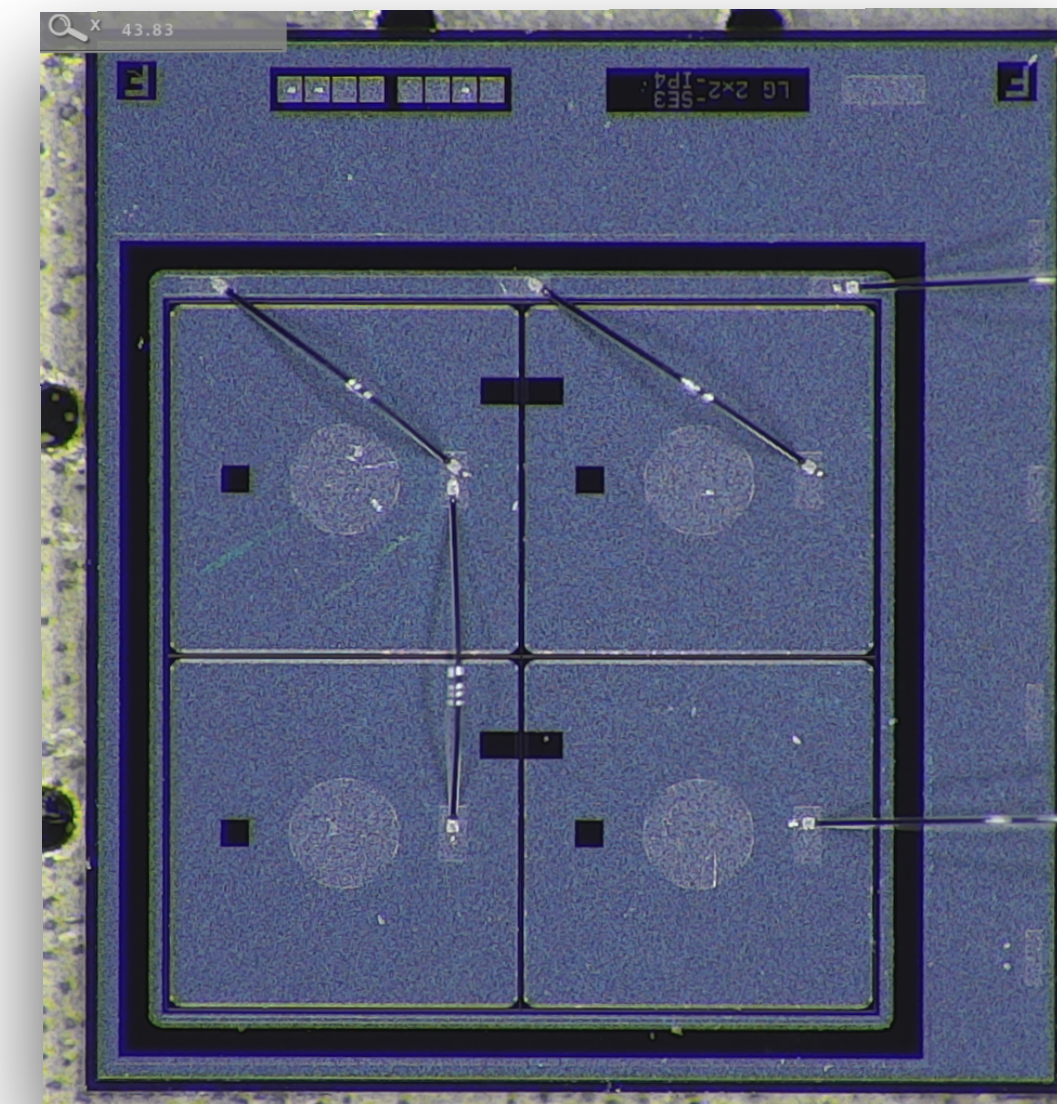
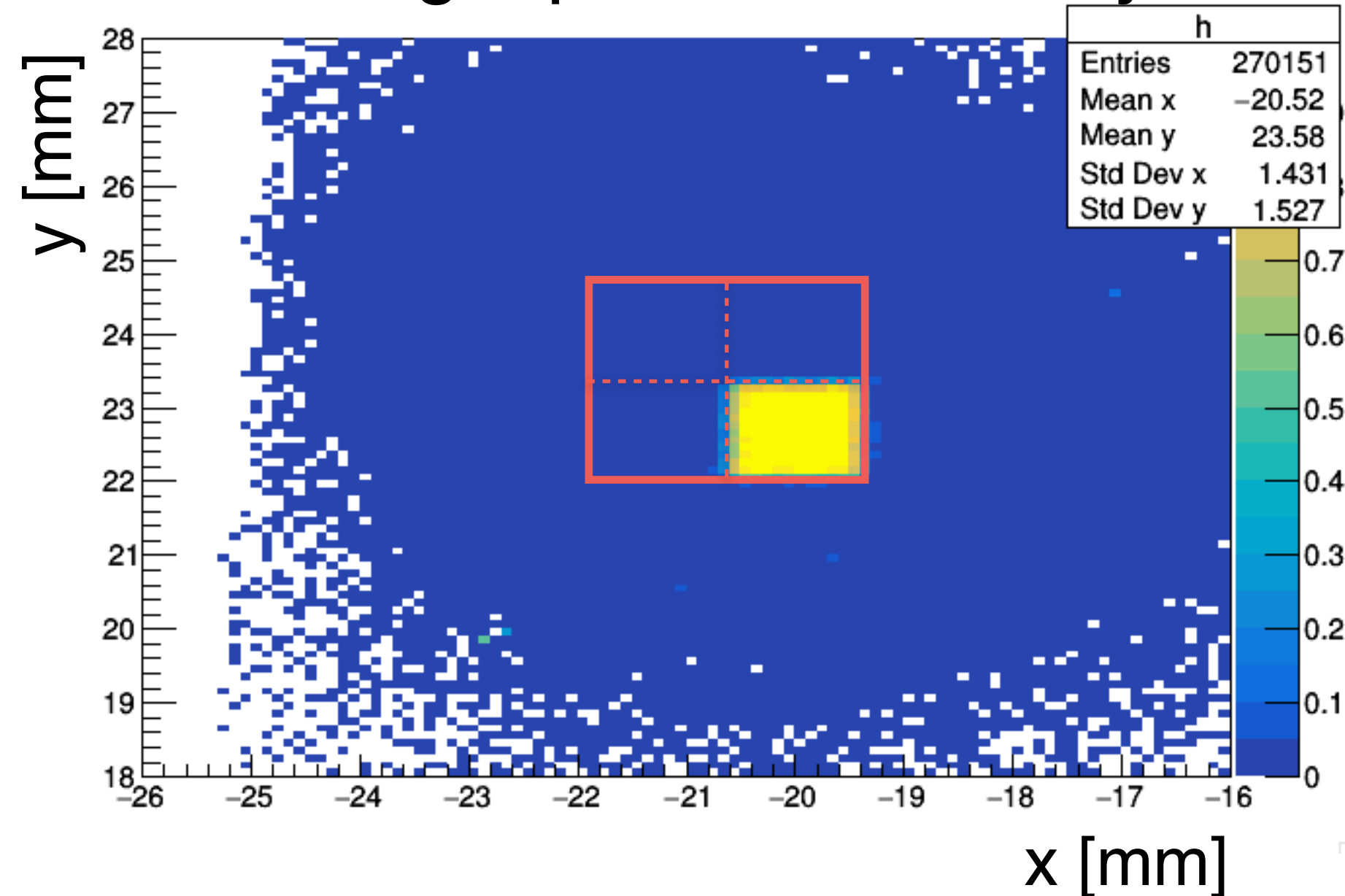
- Measure beam profile with tracker.
- Align each sensor with beam based on single-ch readout.
- Carefully increase bias voltage
  - $\sim 3\text{k}$  protons on sensor per minute. Raise bias 25V after 100-200k protons.

Most sensors in 2x2 geometry  
Most from HPK2  
pre-irradiated  $8\text{e}14\text{-}2.5\text{e}15$  neq

Beam profile

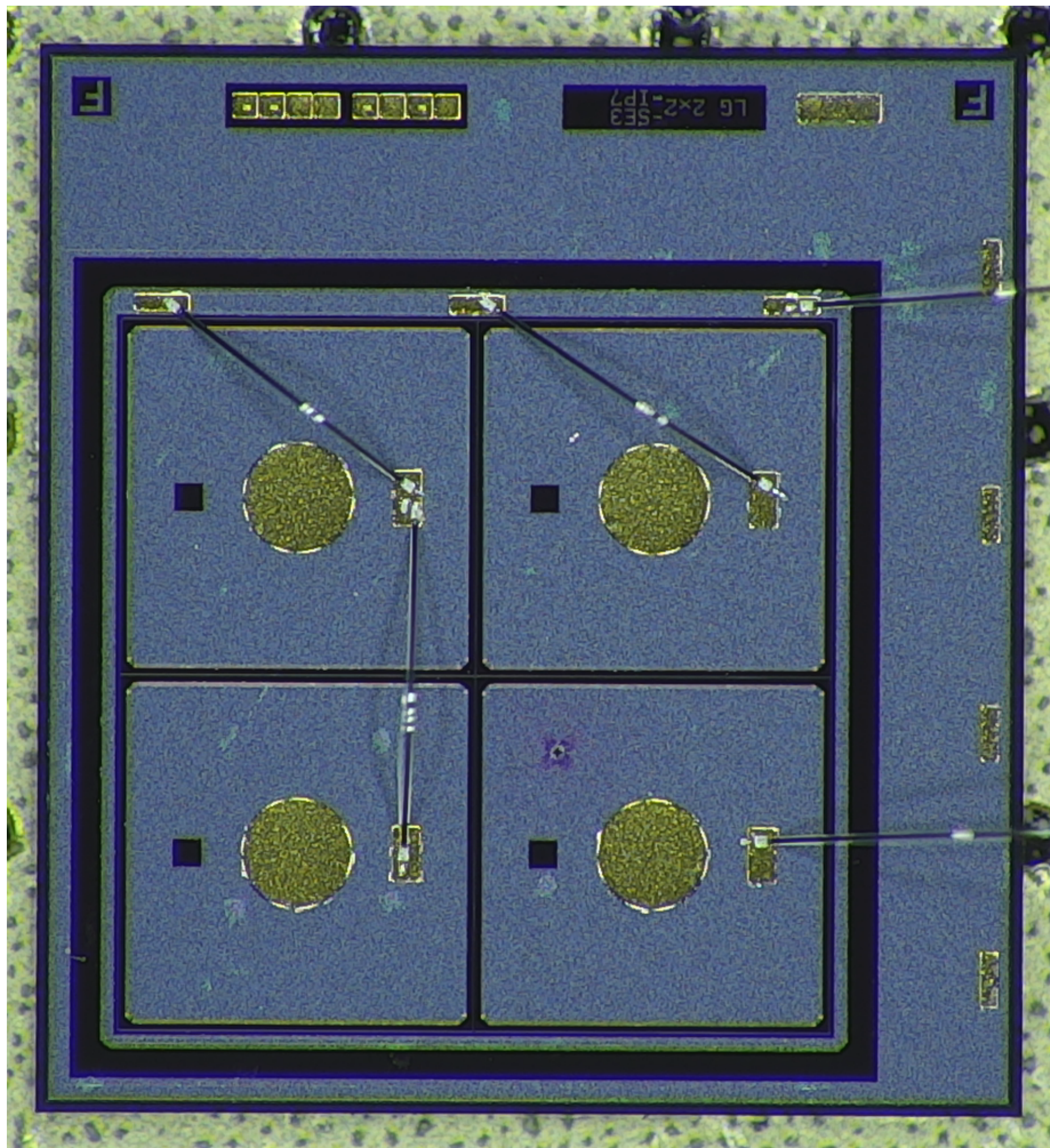


Single pad hit efficiency

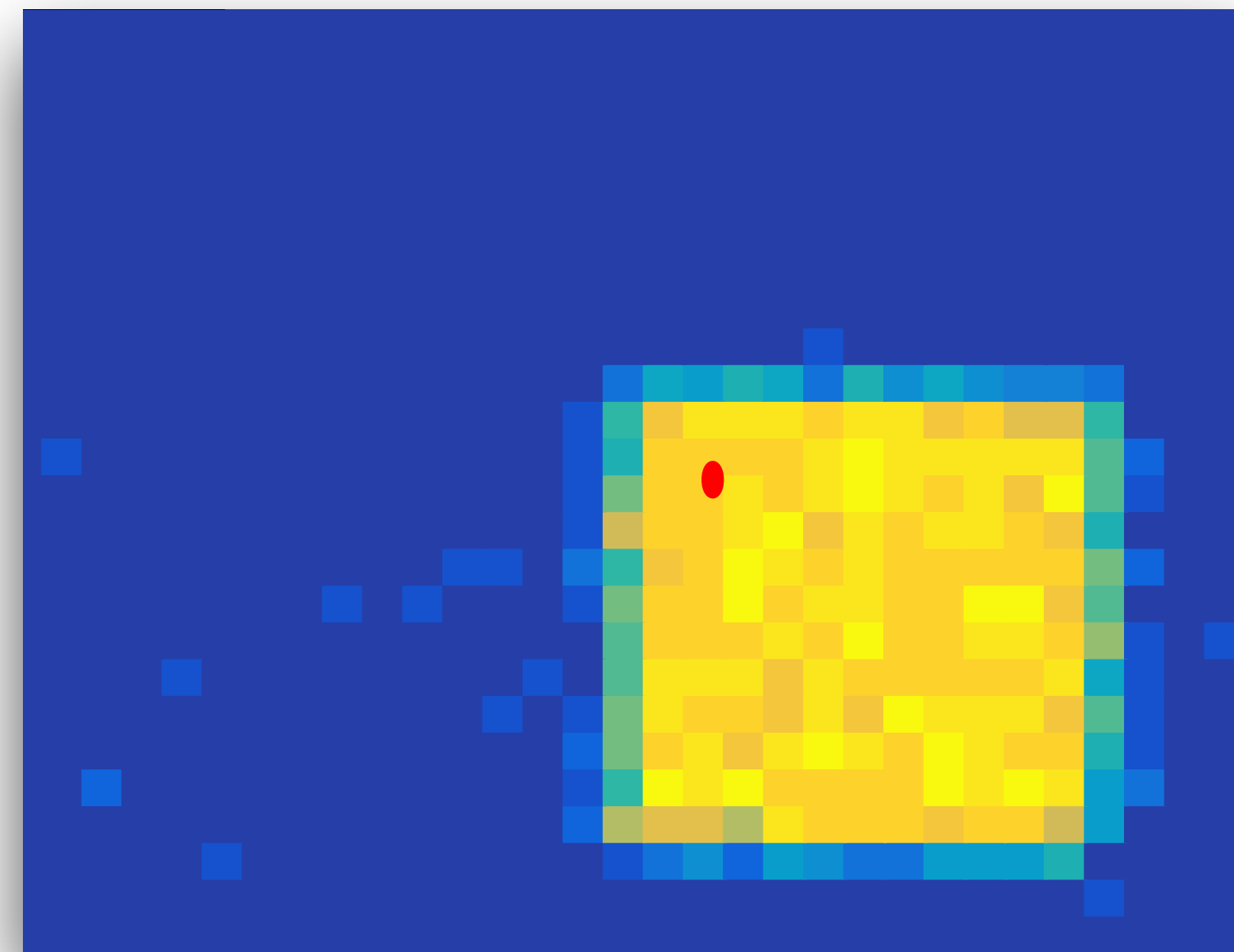


# Example burnout event

HPK 1.5e15 neq/cm<sup>2</sup>



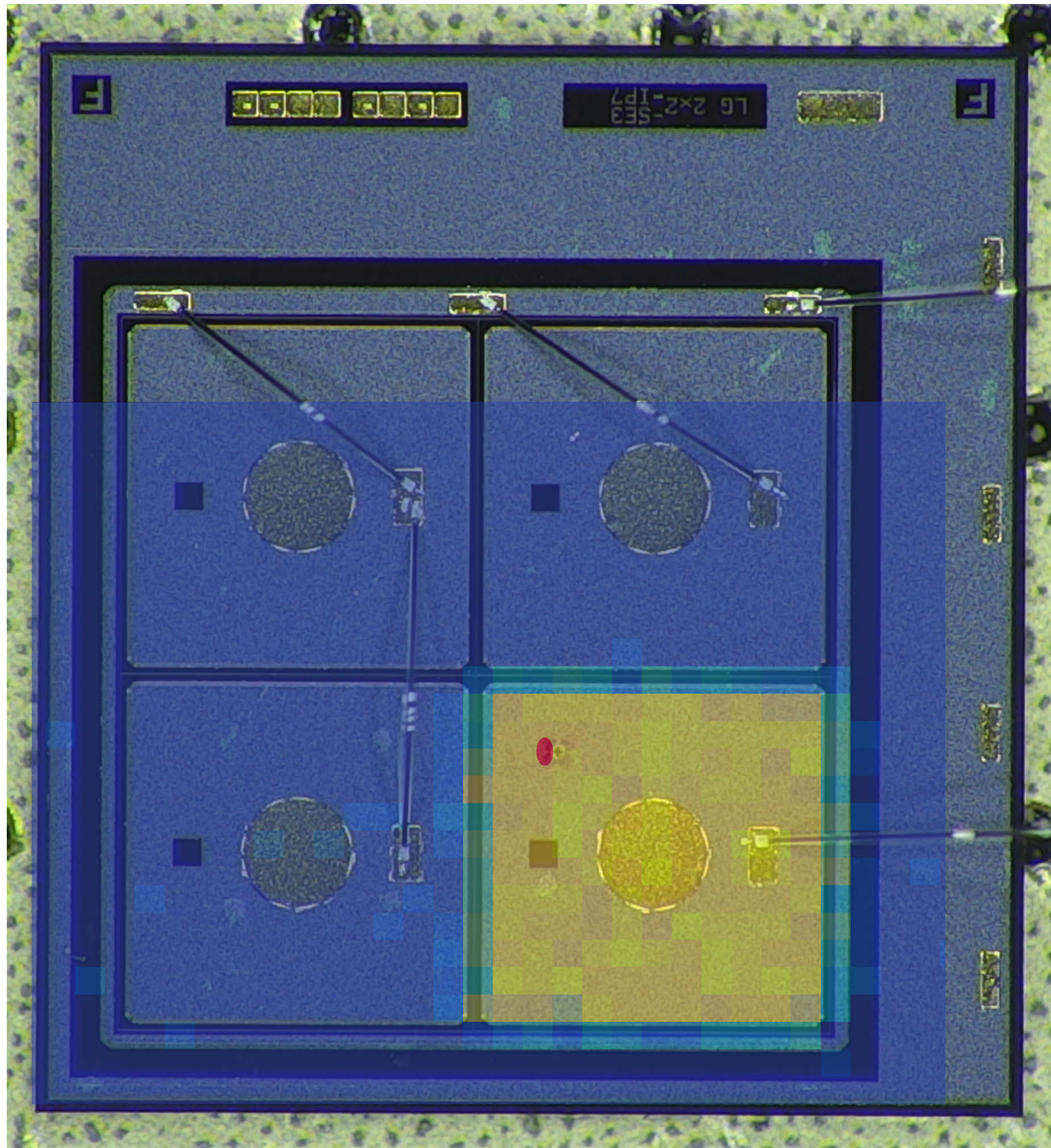
- When death occurs, first observe short on bias supply
- Then, find LGAD waveform indicating moment of death
- Compare track position in fatal event with crater location.



Efficiency map, lower right pad.

# Example burnout event

HPK 1.5e15 neq/cm<sup>2</sup>

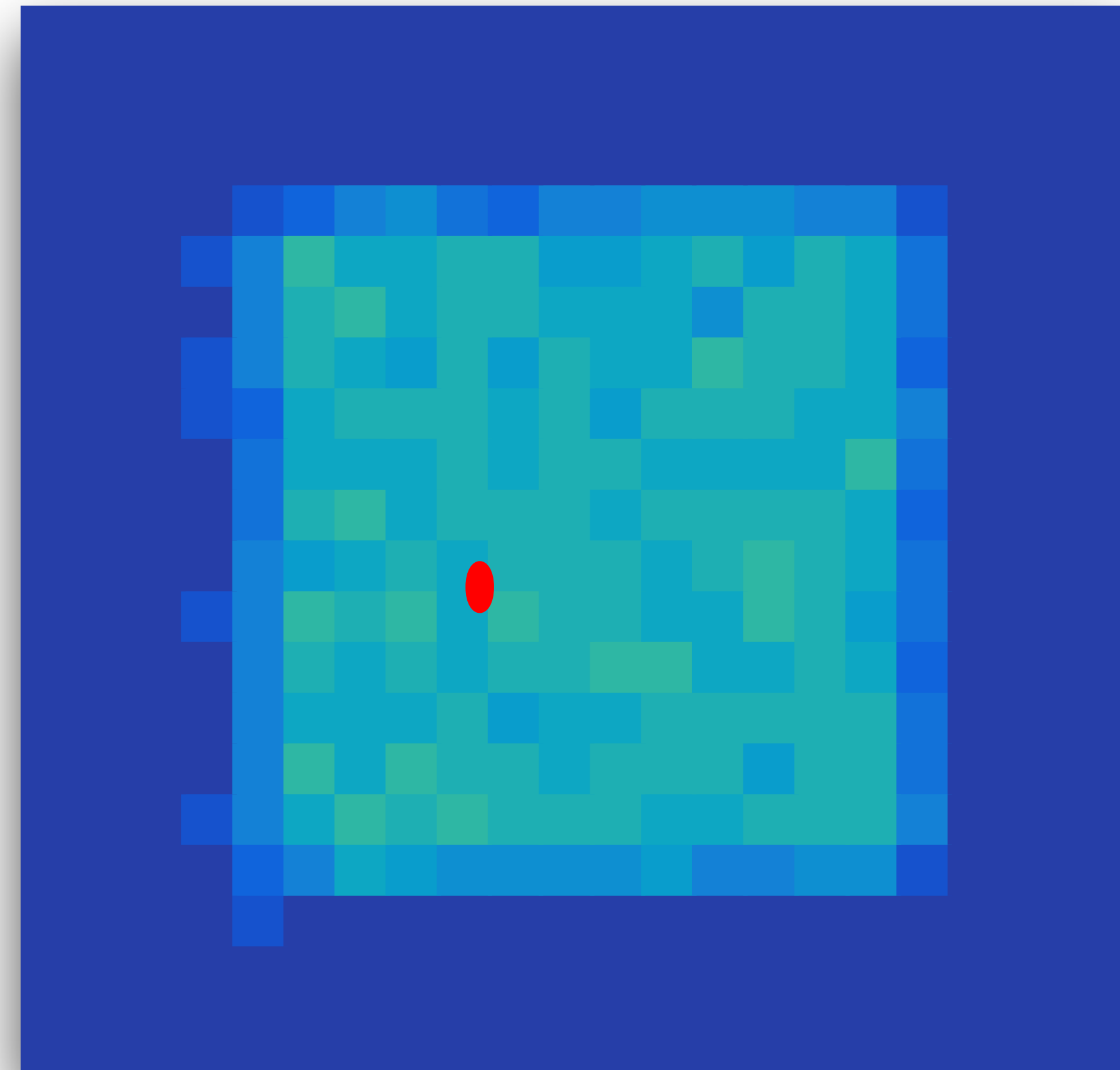
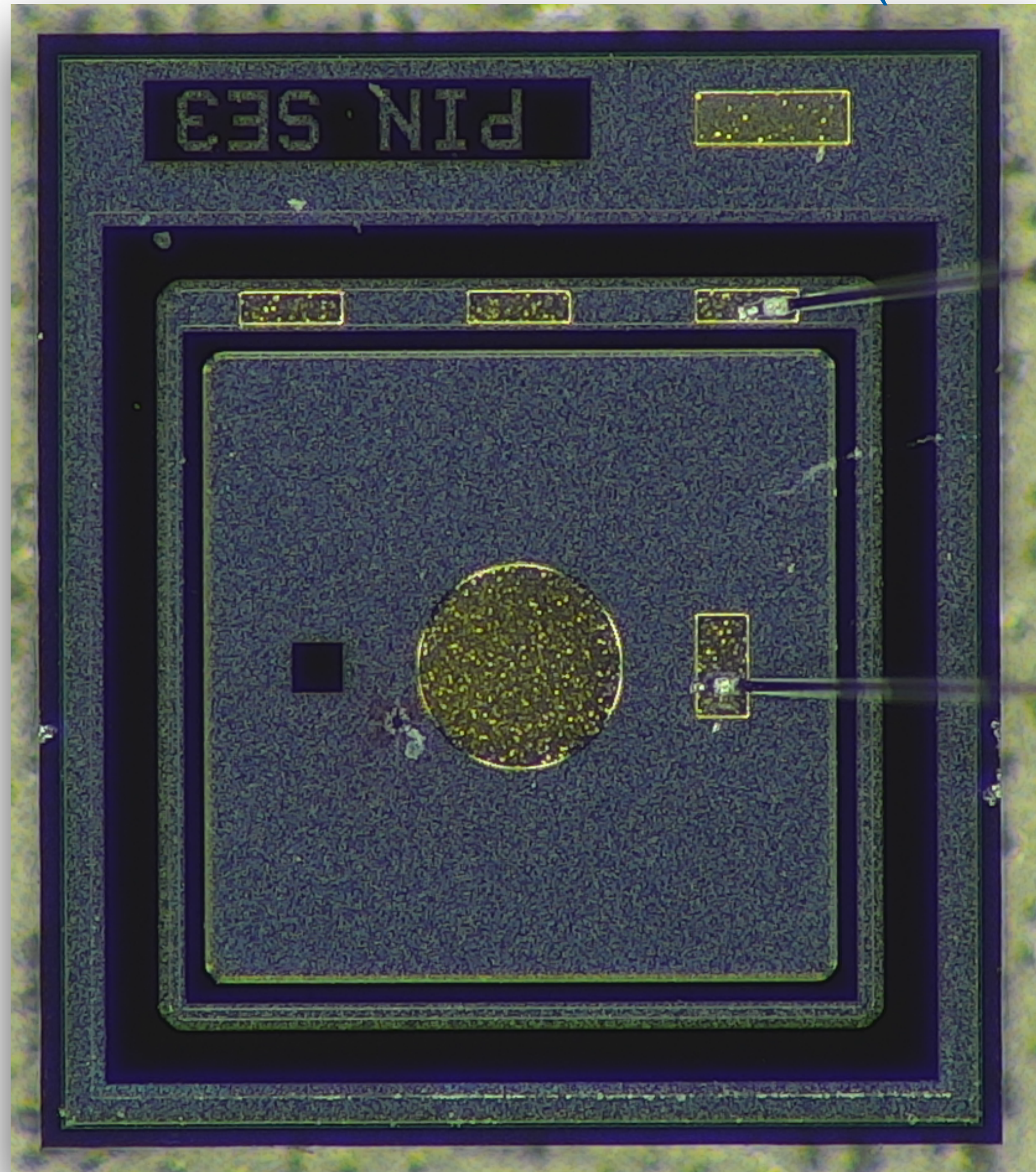


Burnout is decisively caused by proton!



# Burnout in PIN diode

Gamma-irradiated HPK PIN diode (50 micron)



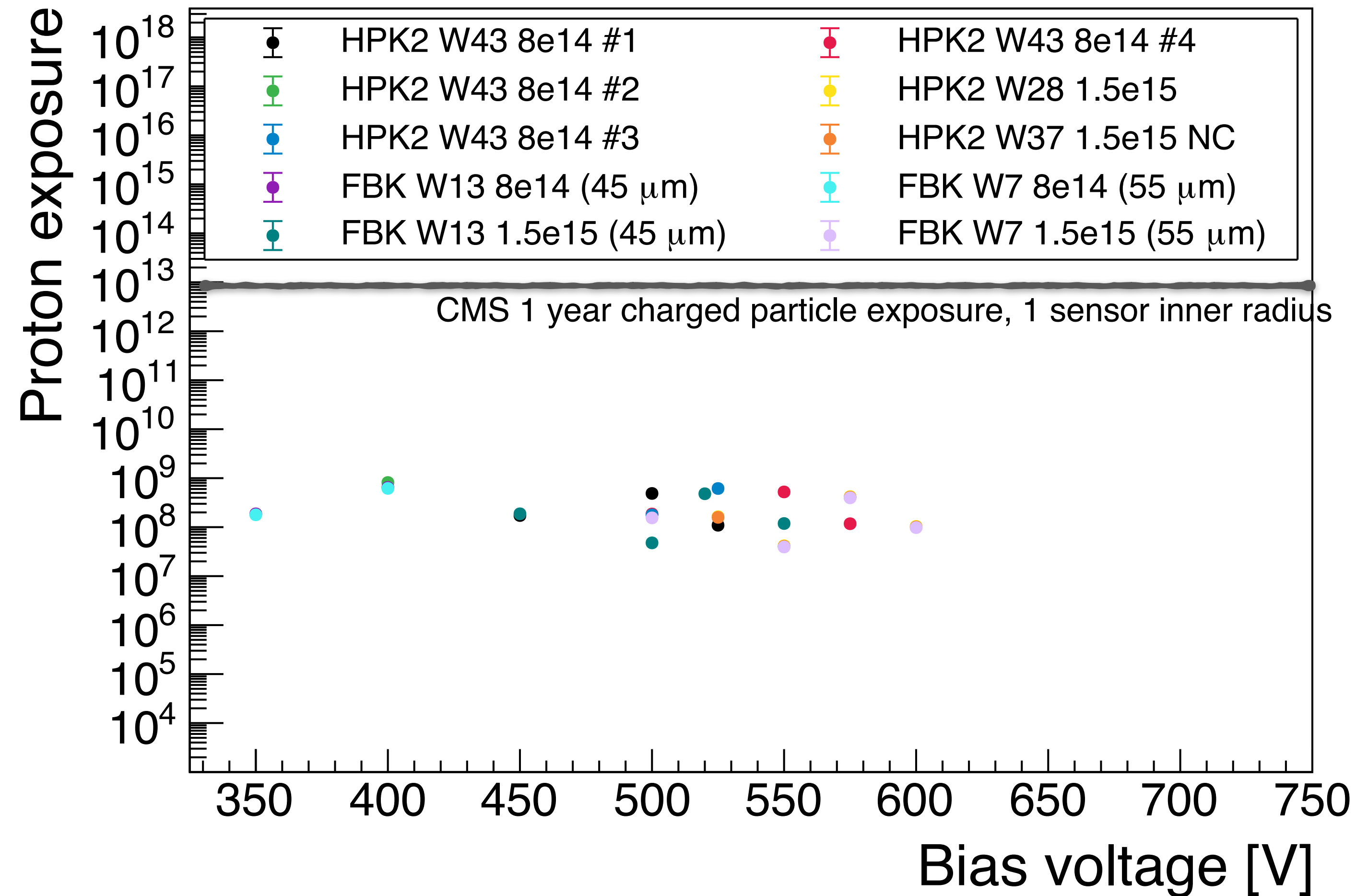
Even diodes die the same way → gain is not needed.

# Conclusions from initial burnout studies (March 2021)

- All 50 micron sensors susceptible to proton-induced burnout at bias  $\geq 600$  V
  - LGADs or PiN; any fluence: all die the same way.
  - ➔ Gain is not important for death mechanism.
  - ➔ Susceptibility depends on voltage & thickness ONLY
- Suspected mechanism:
  - Rare, extremely high ionization events with energy deposit  $> 50$ - $100$  MeV
  - Excess charge produces narrow conductive path across diode at extreme field: burnout due to high current density.
- Several attempted treatments didn't prevent burnout:
  - Encapsulation of sensor
  - Reduce HV capacitance
  - Add resistance to protect from HV supply..

# Initial survival demonstrations

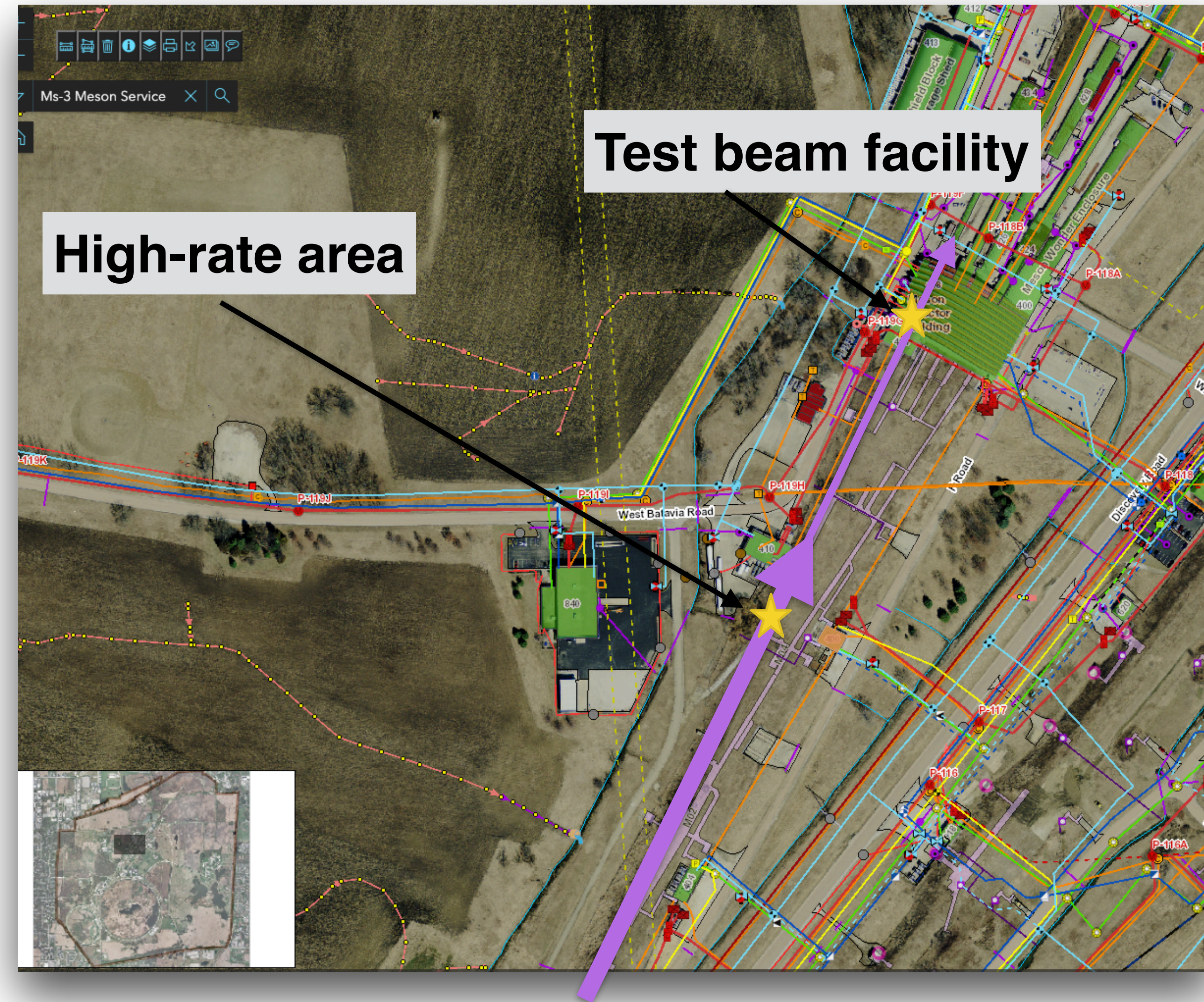
March 2021



- Initial campaign also devoted time to survival demonstration
  - 10 sensors exposed to maximum fluence at test beam facility
  - Probe lifetime at bias slightly lower than burnout threshold.
- No deaths observed in 50 micron sensors  $\leq 575$  V (11.5 V/um)!
- Exposure  $\sim 10^9$  protons
  - But, not quite comparable to CMS environment...

# High-rate survival demonstration

- To achieve flux comparable to CMS, need to use high-rate beam facility, upstream of collimator.
- Achieve  $\sim 10^9$  protons on target per minute, rather than  $10^5$



120 GeV protons

# Sensors used

- 17 irradiated sensors (Ljubljana), on UCSC 1-ch boards
- 2 pre-rad sensors for beam monitor, FNAL 26-ch boards
- All sensors in 5x5 geometry.

	Fluence [neq/cm <sup>2</sup> ]	# sensors
HPK2, 50 micron	8e14	x4
	1.5e15	x4
FBK3.2, 45 micron	8e14	x1
	1.5e15	x3
FBK3.2, 55 micron	8e14	x1
	1.5e15	x4



# New setup at high-rate area (December 2021)

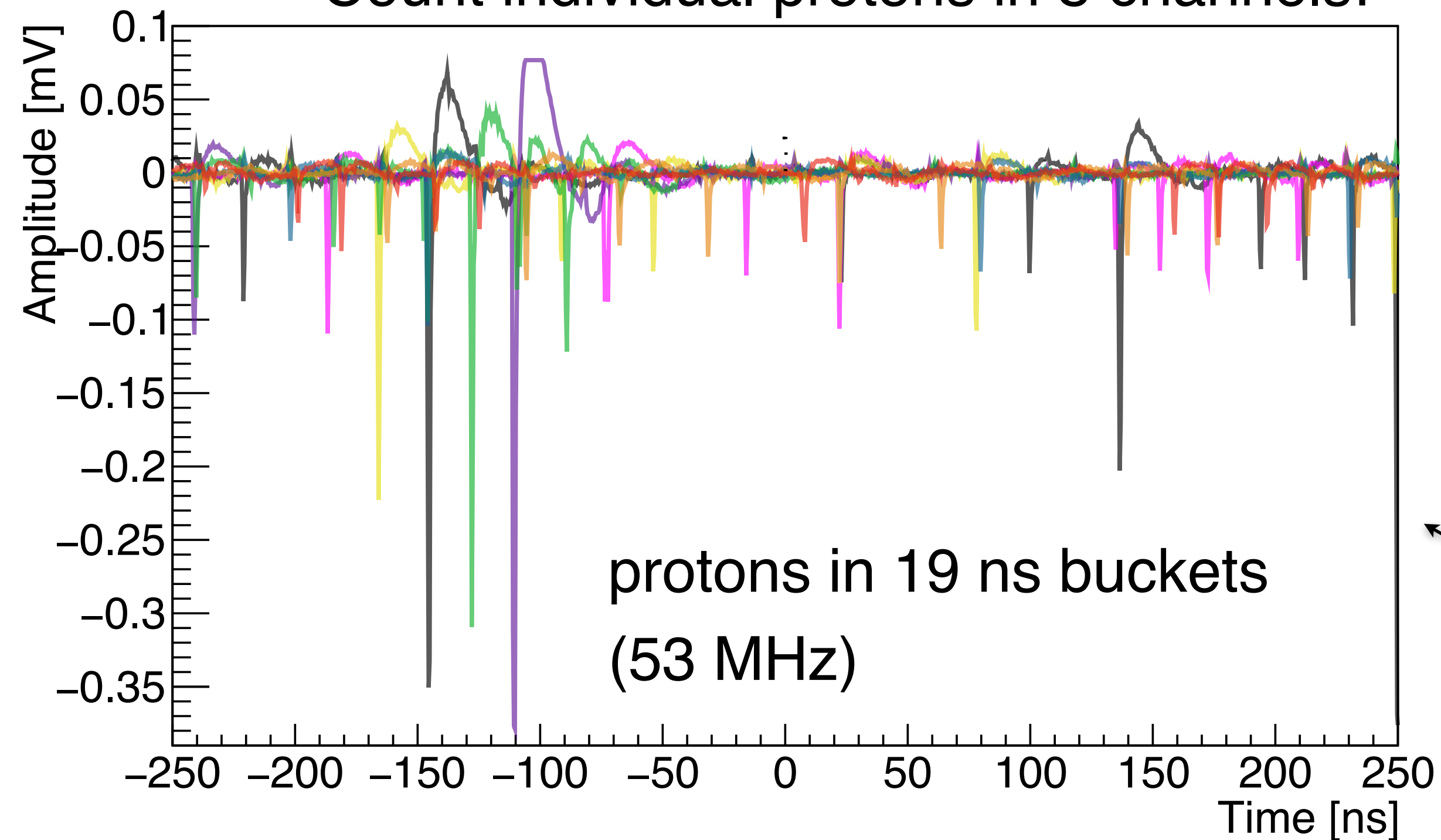
- Built new setup to support 20 LGADs in high-rate beam
- Hazardous environment..
  - High radiation, frequent SEUs, oxygen deficiency hazard, many barriers to entry



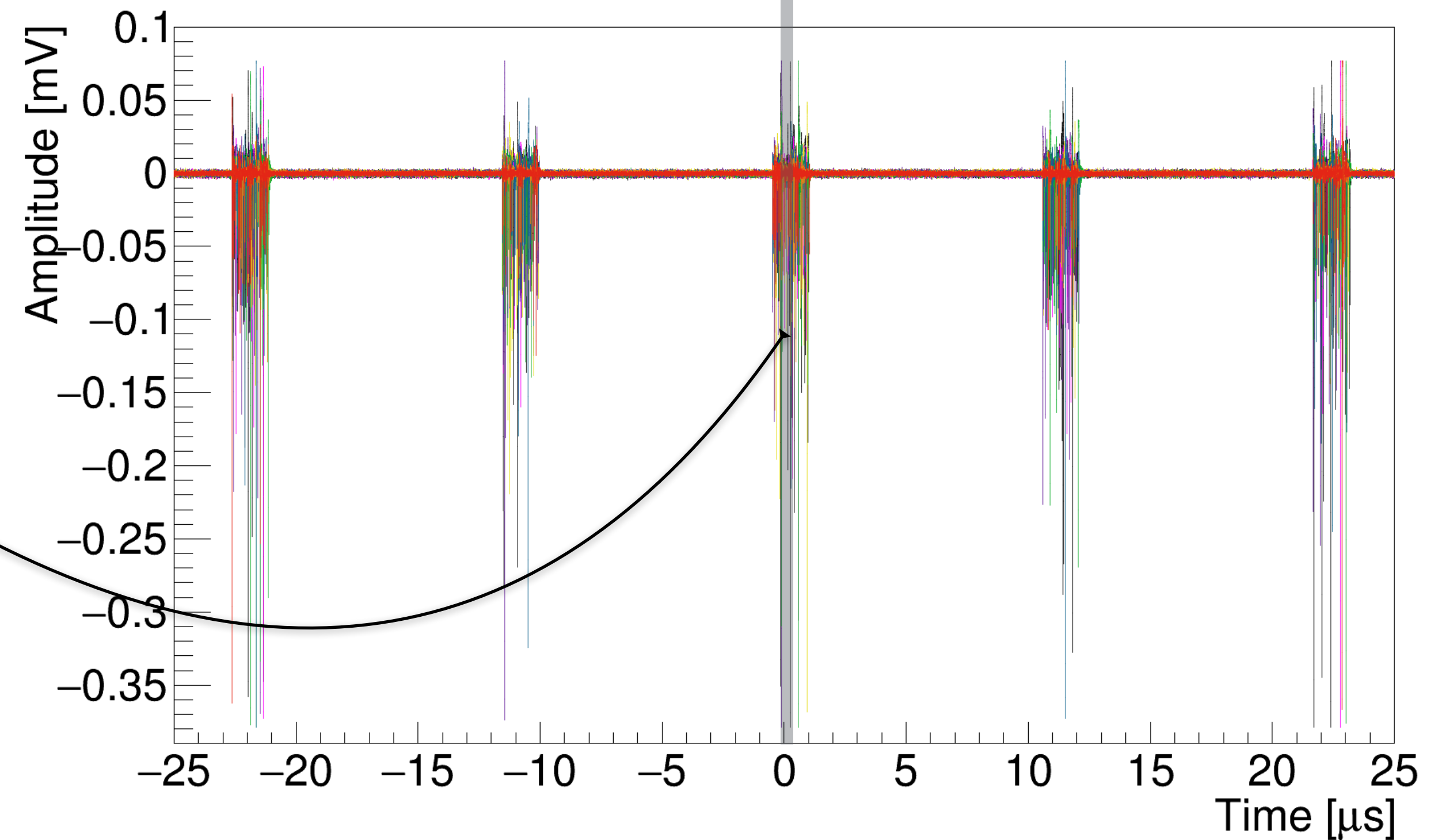
# Measuring beam intensity

- Use LGADs themselves to monitor beam intensity!
- Record one waveform per spill, for 10 millisecond duration. Count signals in 8 ch

Count individual protons in 8 channels!



1.6  $\mu\text{s}$  “batches”, repeated each 11.2  $\mu\text{s}$  “cycle”

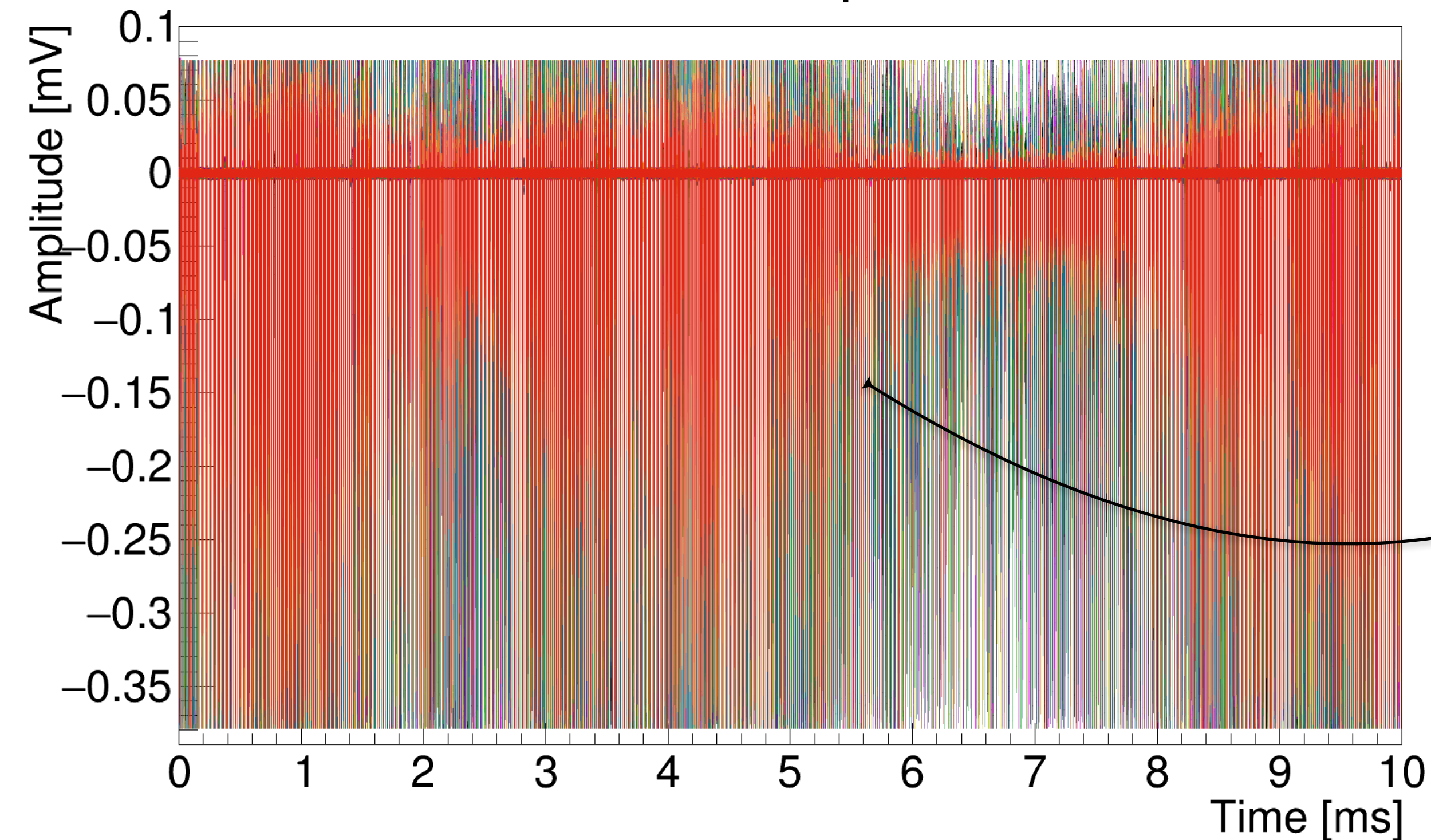


Receive about 400k batches in 4 s, each minute.

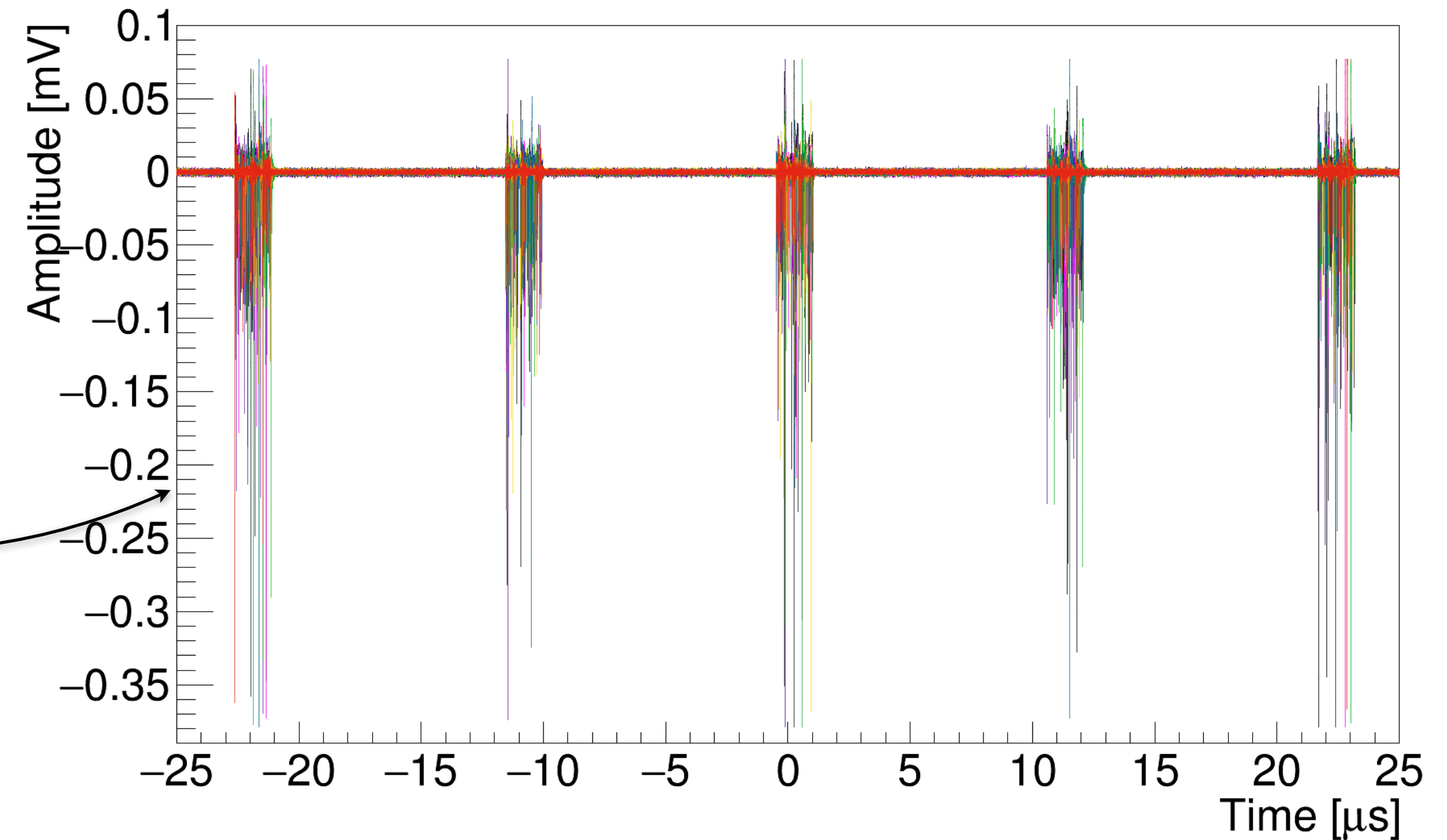
# Measuring beam intensity

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10 ms snapshot



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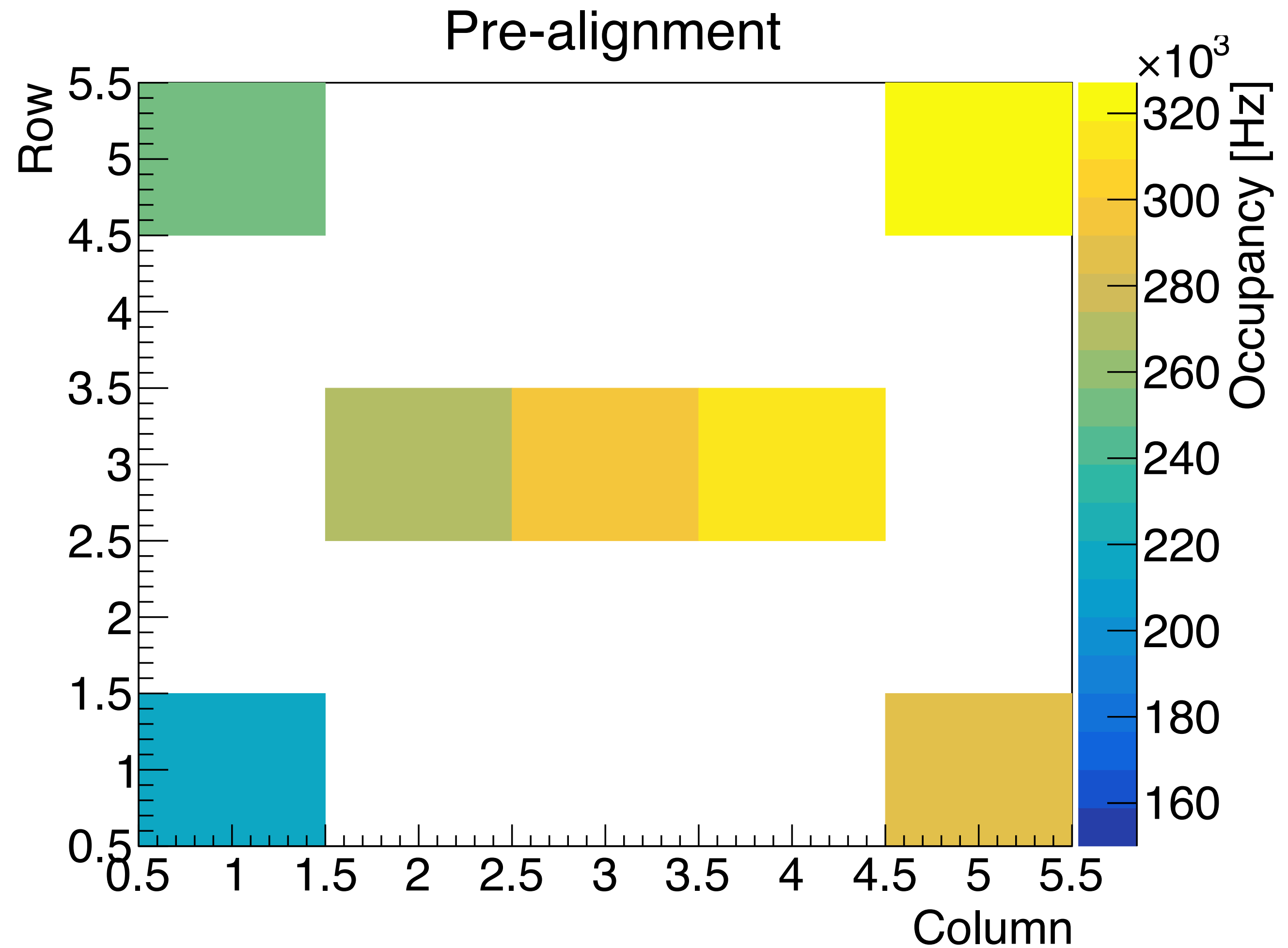


- Long exposures reveal time structure of beam and allow calibrating delivered flux.
  - Large variation on  $O(1 \text{ ms})$  time scale
  - Moderate variation on  $O(1 \text{ s})$  time scale.



# Aligning to beam

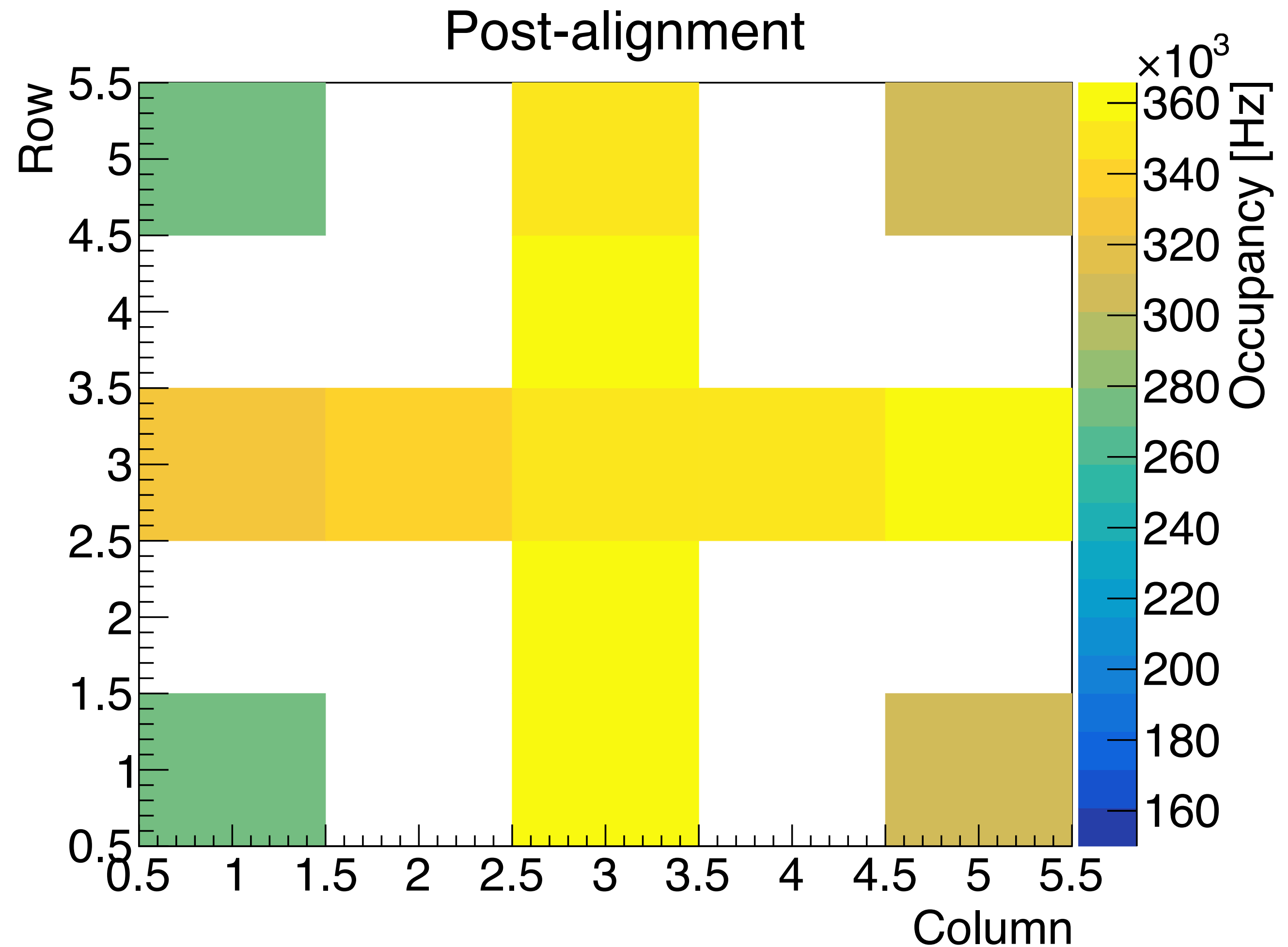
- Study occupancy across sensor w/ 8-ch
- Follow gradient to align sensor



- With best alignment, occupancy in edge pads is 80-90% of center (wide beam)
- Final sensor occupancy: **200M protons / sensor / spill**
  - x2000 larger flux per sensor than max achieved in regular test beam (slightly less than expectation)

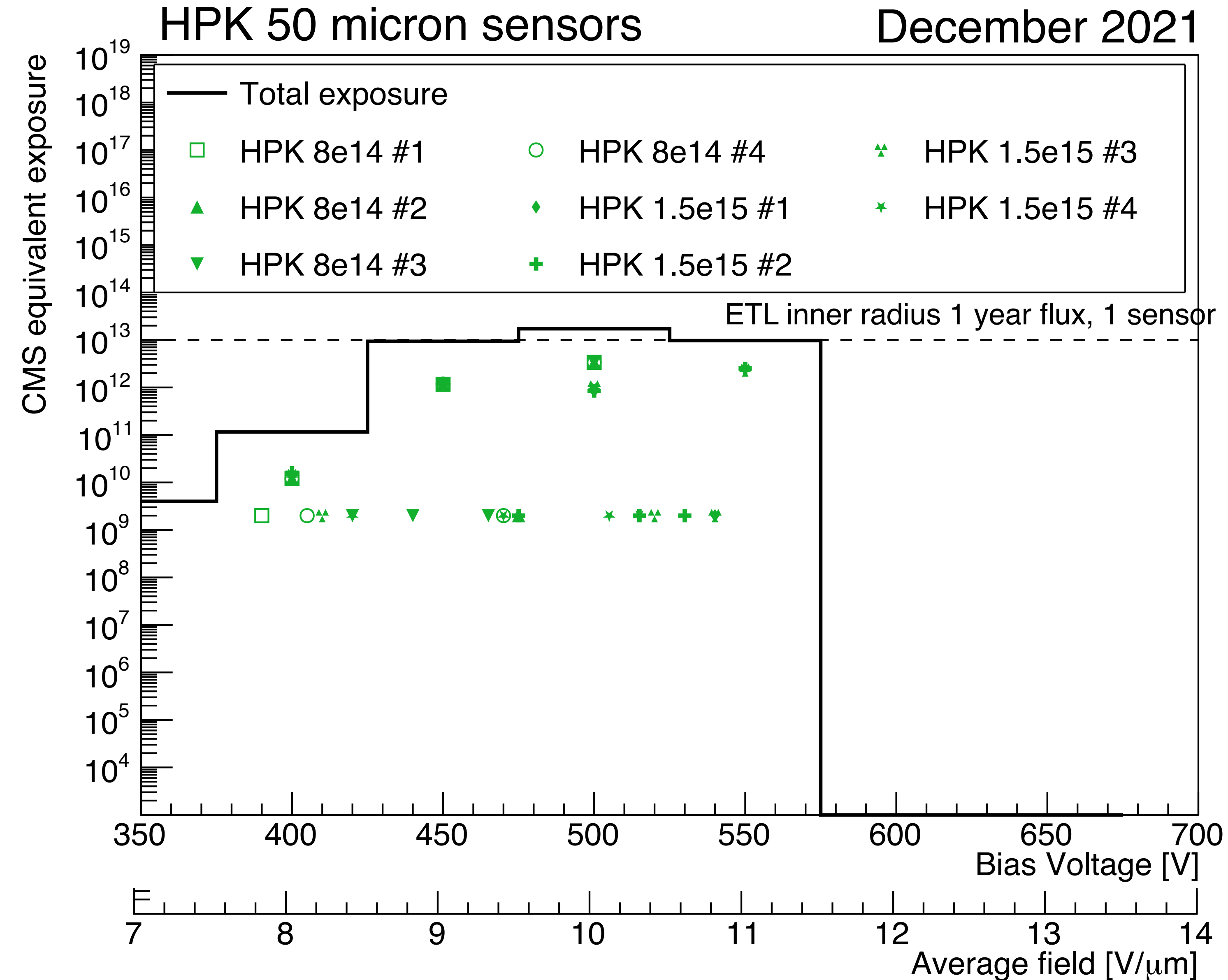
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# HPK exposures

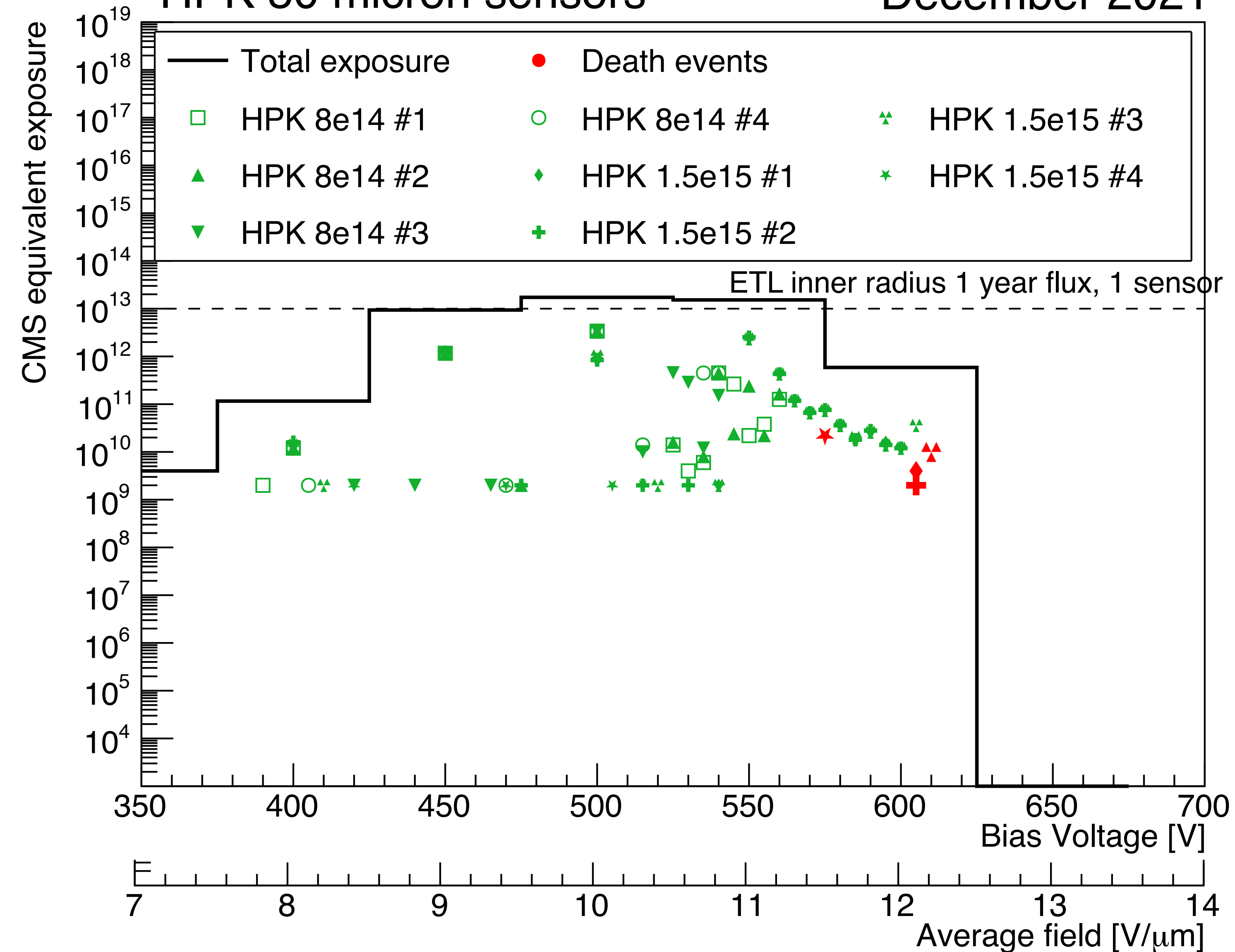


- Delivered  $10^{13}$  protons at 450, 500, and 550 V with no deaths!
- Comparable exposure to 1 year flux for a sensor in ETL
- Similar results for 45 and 55 micron sensors from FBK

# HPK exposures

HPK 50 micron sensors

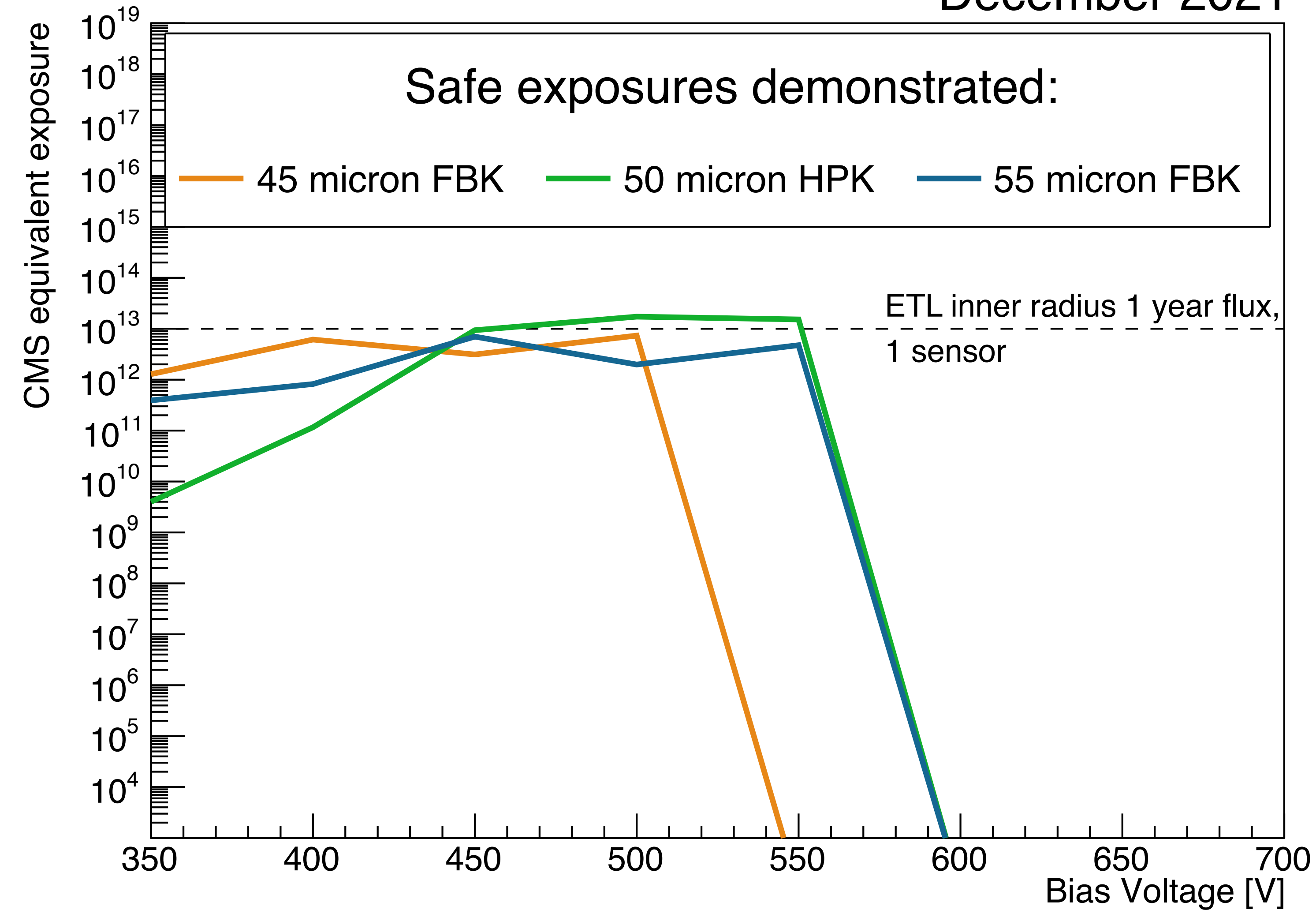
December 2021



- After survival phase, continue ramping to look for deaths beyond 11 V/um
- 4x HPK 1.5e15 deaths:
  - 575 V, 605 V, 605 V, 610 V
  - 11.5-12.2 V/um

# Exposure summary

December 2021



- Demonstrated safe operation with flux comparable to 1 year at CMS in all 3 thicknesses!
- SEB threshold seems to roughly scale with thickness ( $\sim$  constant field)
- **FBK sensors with high radiation tolerance avoid dangerous region for entire life of detector.**

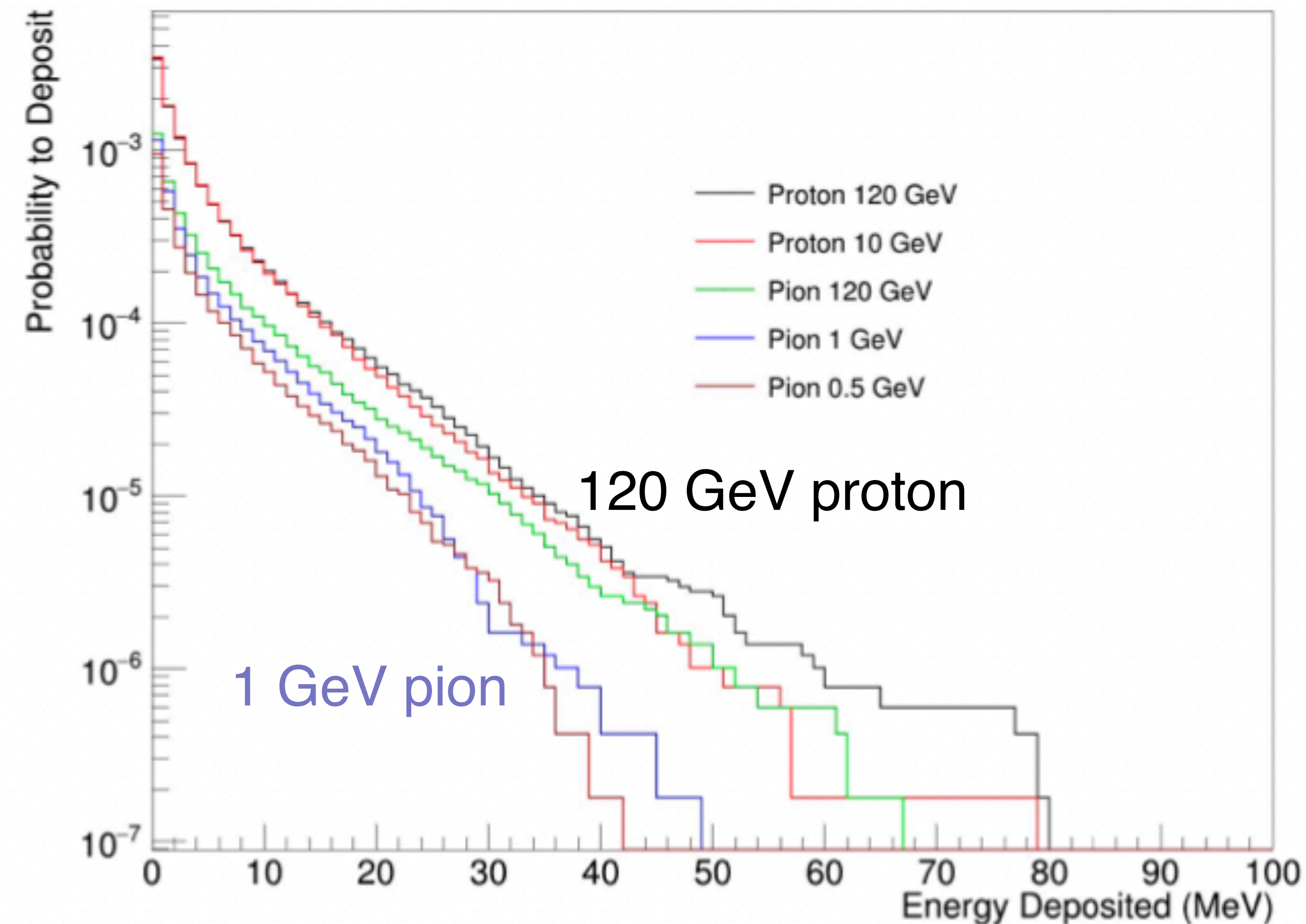
# Summary

- Two intensive test beam campaigns completed in 12 months.
- Understanding of single-event burnout mechanism greatly improved
  - Definitively caused by single-particle interaction
  - Susceptibility driven by thickness and bias voltage.
- Safe regions of operation established through realistic, high-rate tests probing flux comparable to the HL-LHC environment.
- Burnout can be avoided for full life of the CMS ETL without cost to performance.



# Proposed burnout mechanism

Probability to deposit at least X MeV in 50  $\mu\text{m}$  (GEANT4)



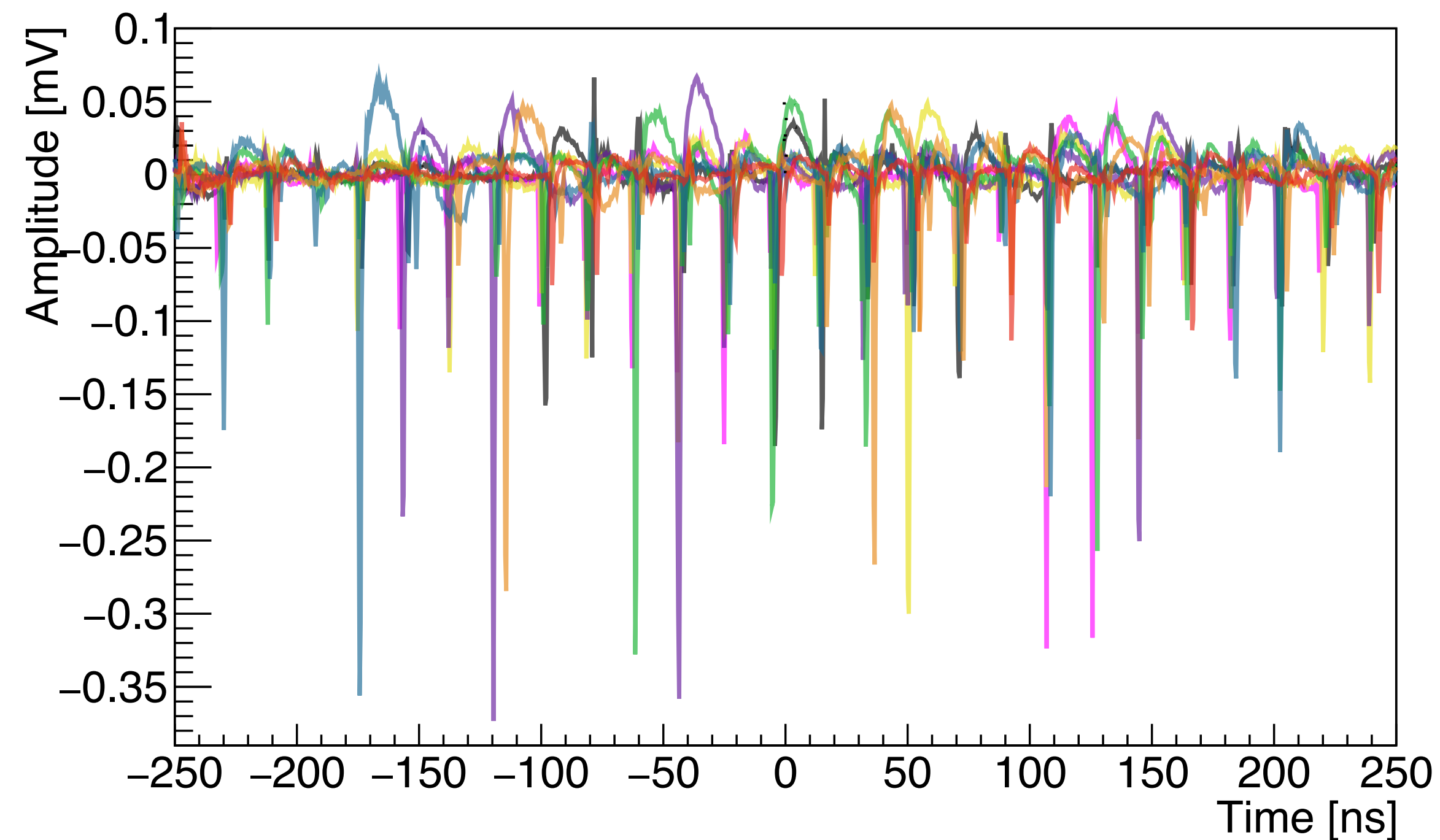
- Rare, large ionization event “Highly Ionizing Particle”
  - Excess charge leads to highly localized conductive path
  - Large current in narrow path  $\rightarrow$  “Single Event Burnout”
- Estimate  $>20$  MeV deposit needed based on rate
- 120 GeV protons are  $\sim 10x$  more likely to yield burnout than typical LHC charged particles (e.g. 1 GeV pion)
- Need to probe farther in tail to ensure safety at lower bias voltage...



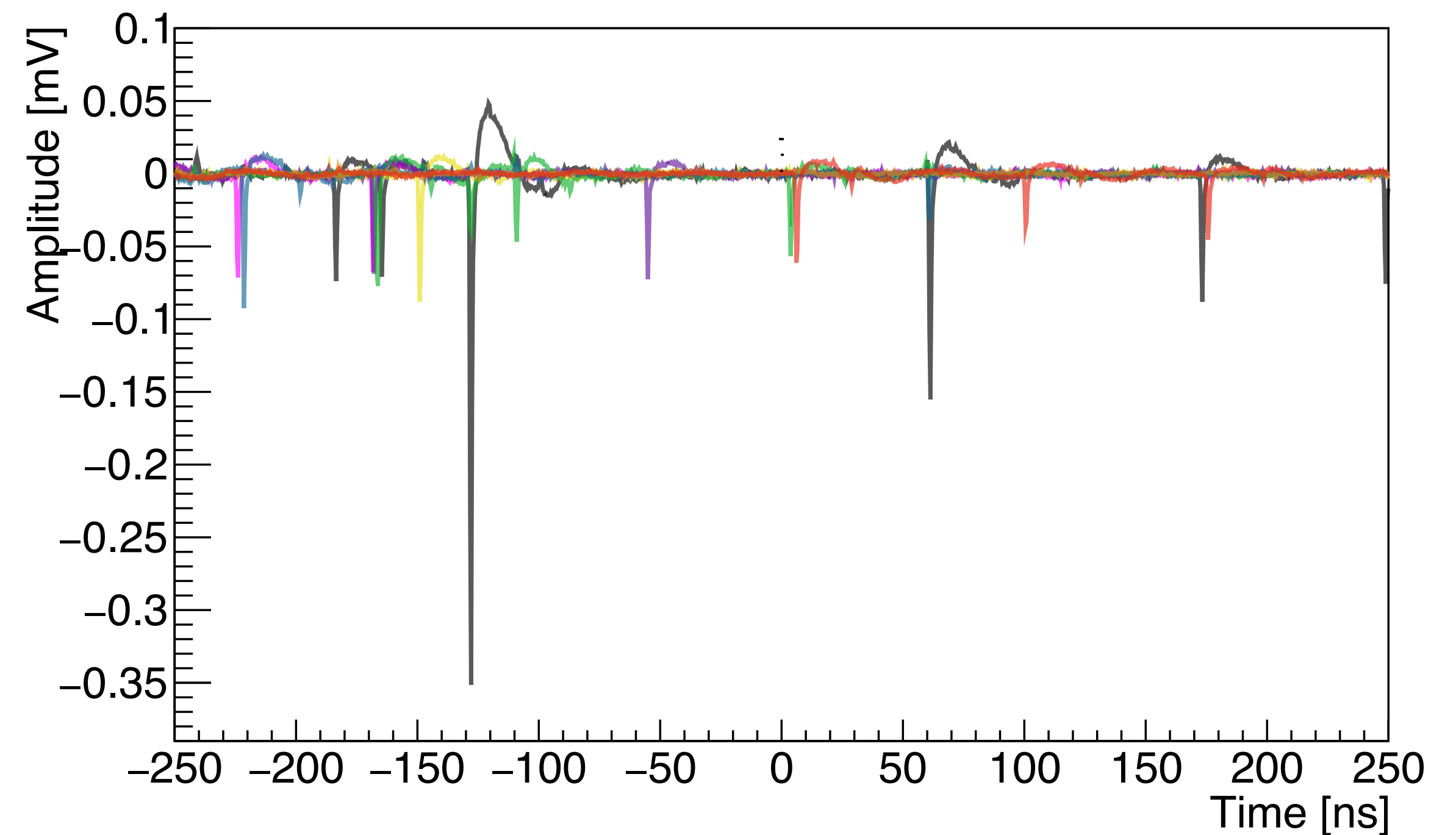
# Measuring beam intensity

- Use LGADs themselves to monitor beam intensity!
- Record one waveform per spill, for 10 millisecond duration. Count signals in 8 ch

High-occupancy batch (4 ms after trigger)

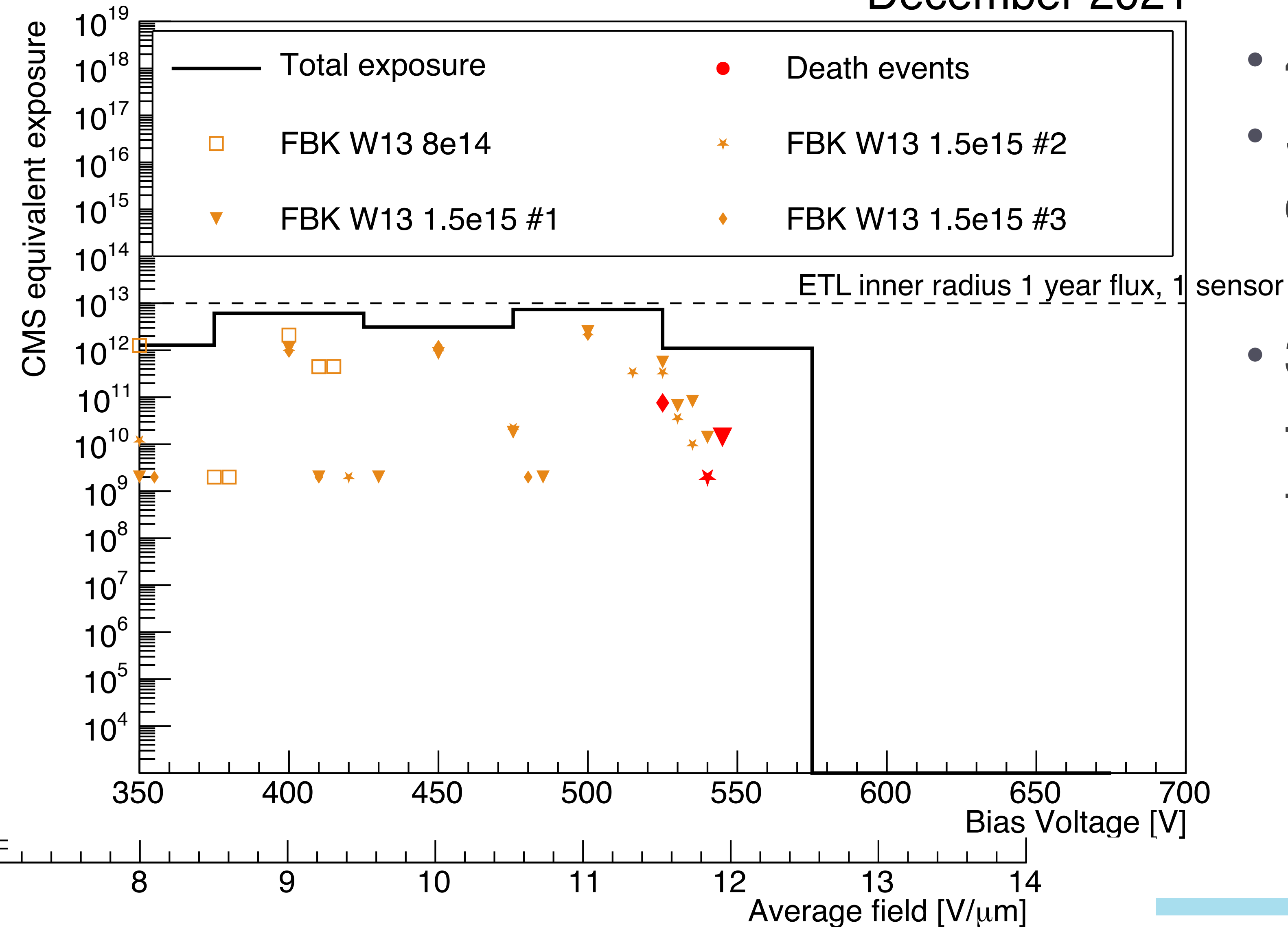


Low-occupancy batch (7 ms after trigger)



# 45 micron FBK

December 2021

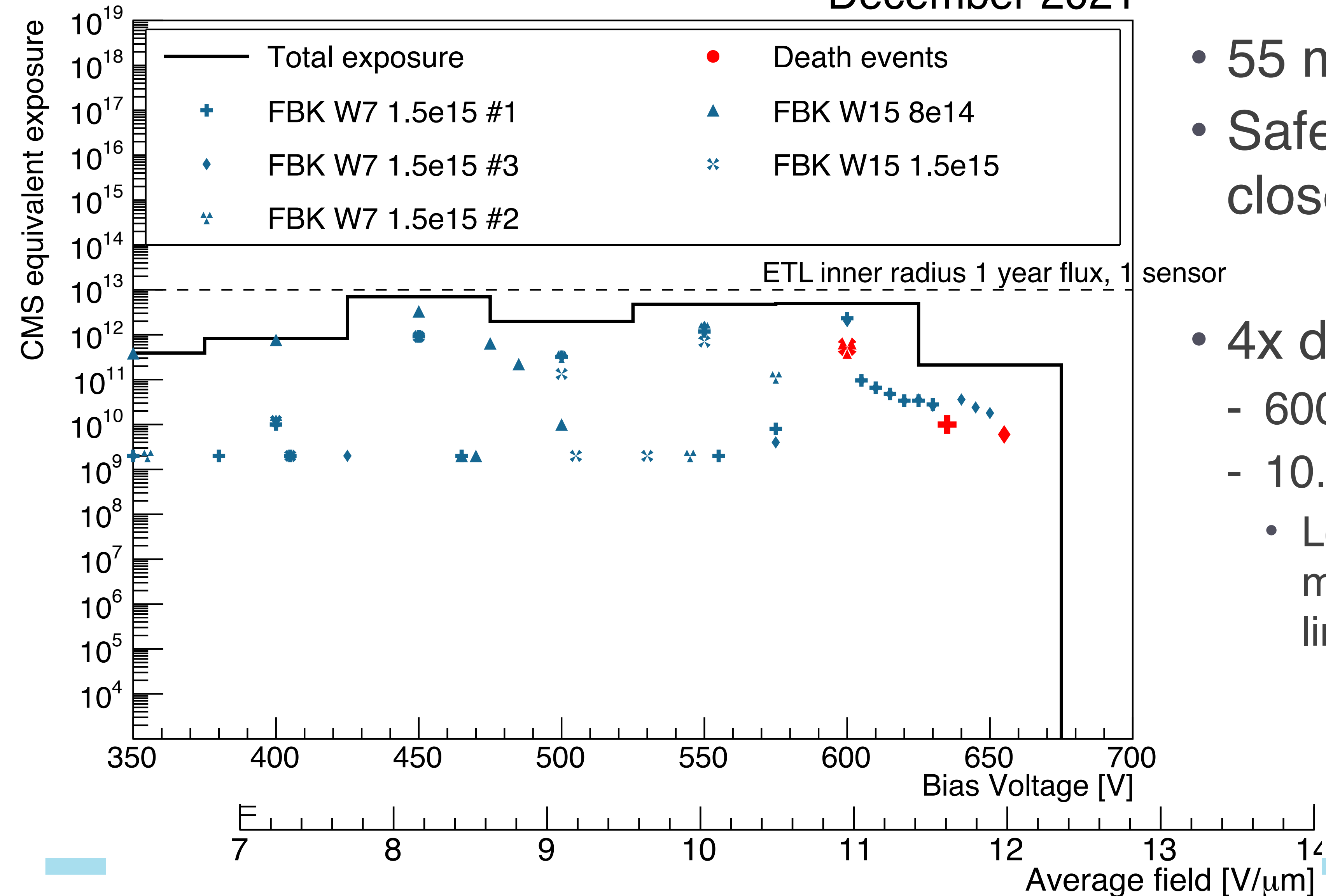


- 45 micron FBK sensors
- Safe operation at 9-11  $V/\mu\text{m}$ , close to CMS 1-year flux.

- 3x deaths in  $1.5e15$ :
  - 525 V, 540 V, 545 V
  - 11.7  $V/\mu\text{m}$  to 12.1  $V/\mu\text{m}$

# 55 micron FBK

December 2021

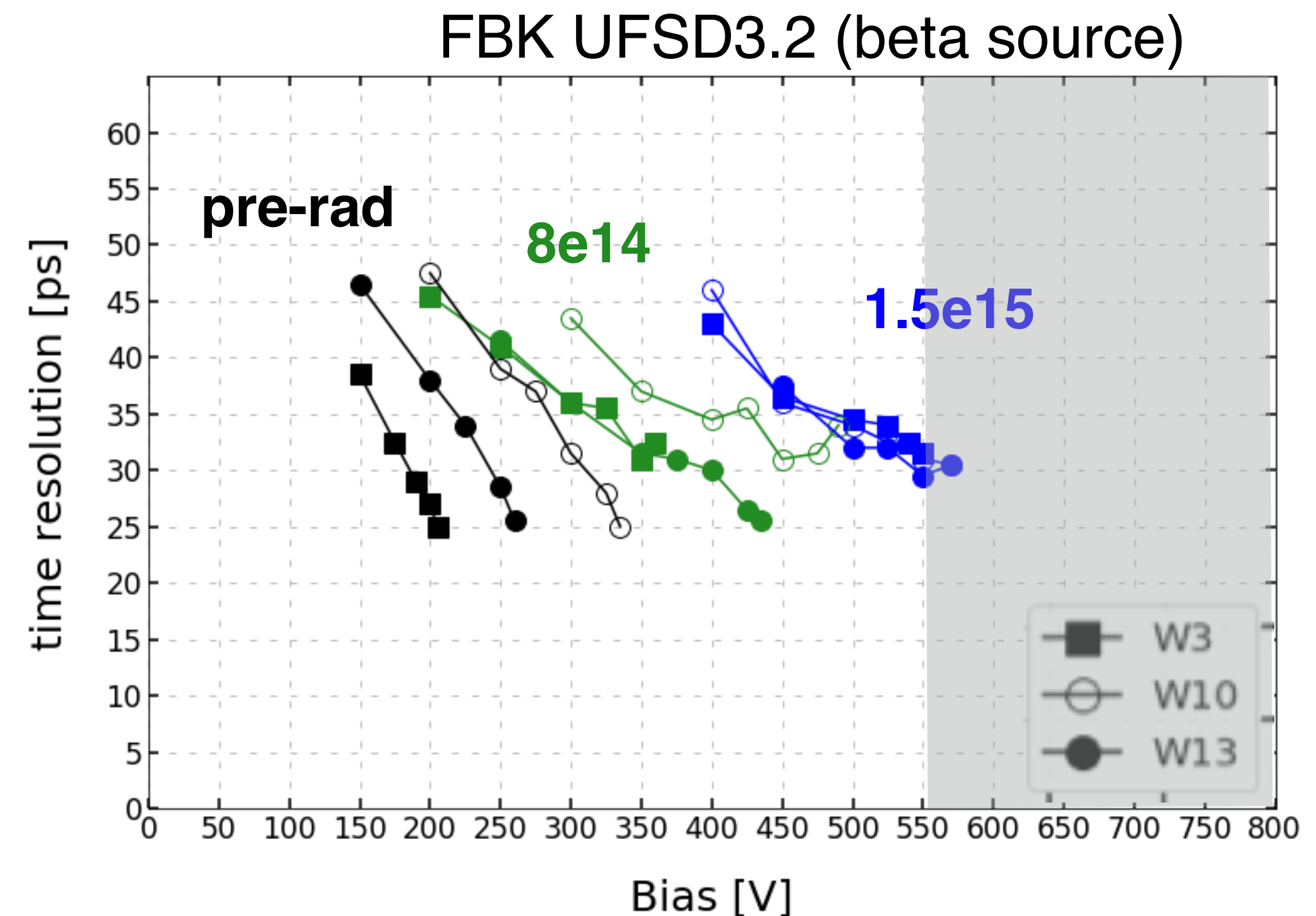
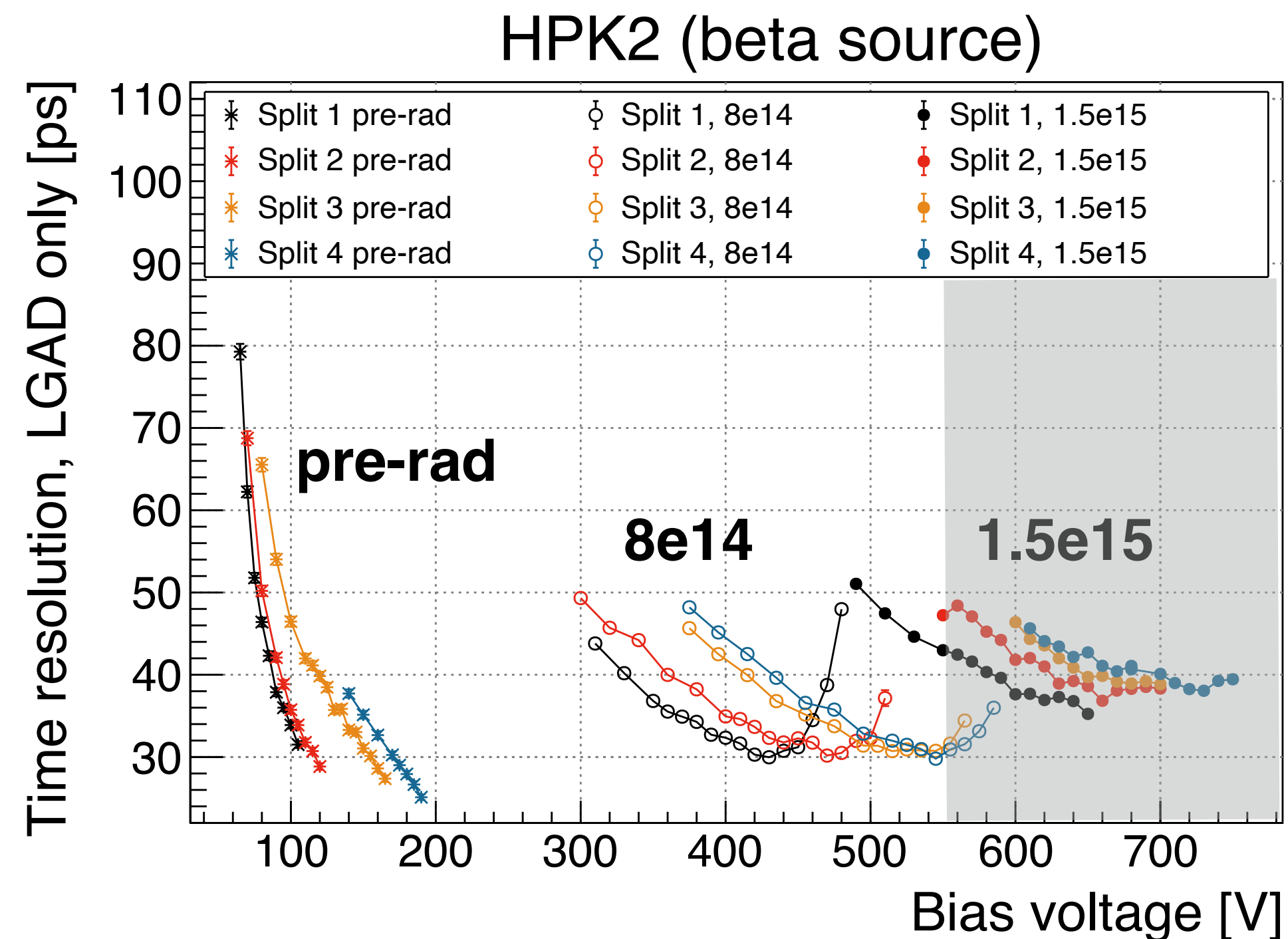


- 55 micron FBK sensors
- Safe exposures in 8-10 V/ $\mu\text{m}$ , close to CMS 1-year flux.

- 4x deaths in 1.5e15:
  - 600 V, 600 V, 640 V, 645 V
  - 10.9 V/ $\mu\text{m}$  to 11.9 V/ $\mu\text{m}$ 
    - Lower field at death than 45 or 50 micron sensors—scaling is not quite linear

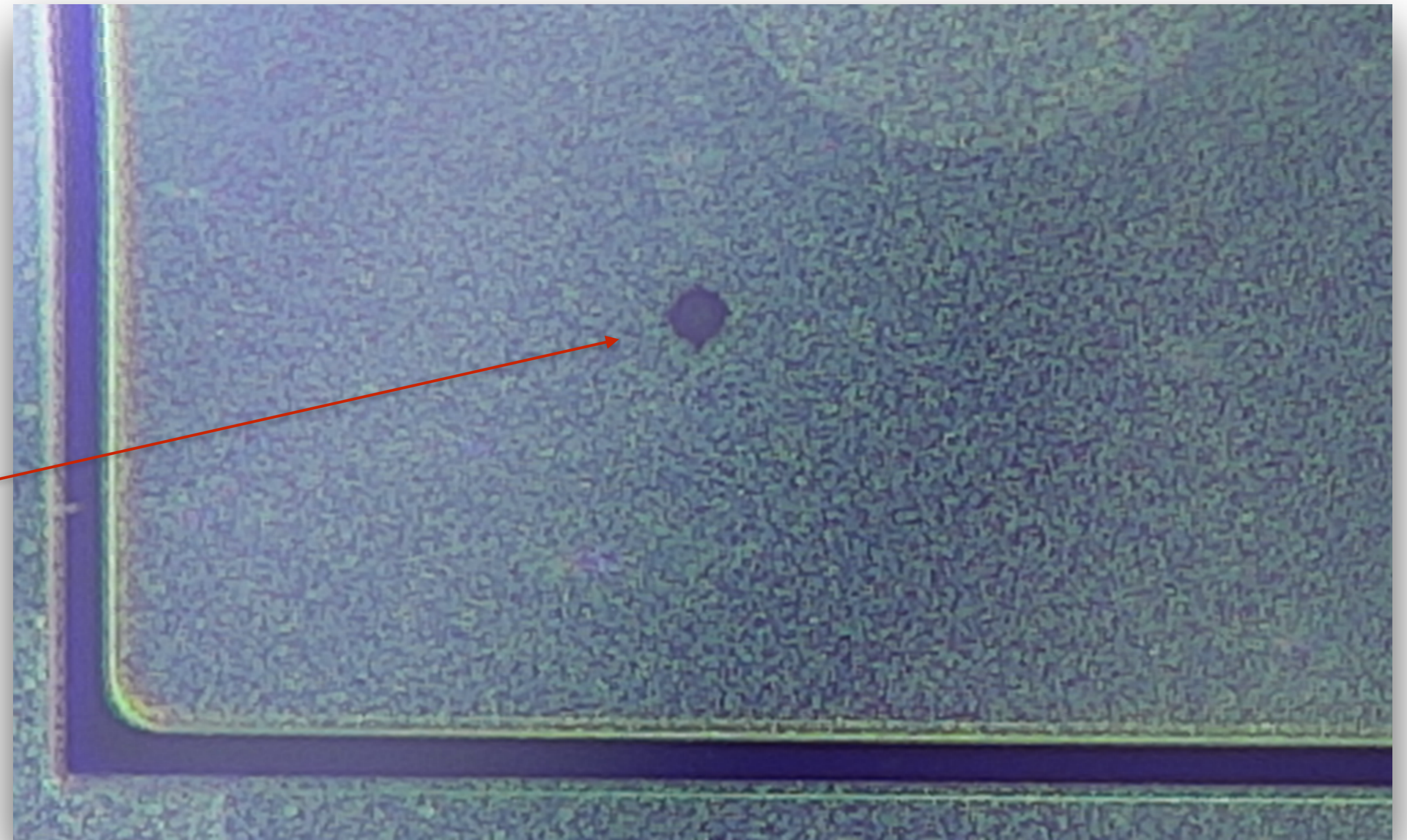
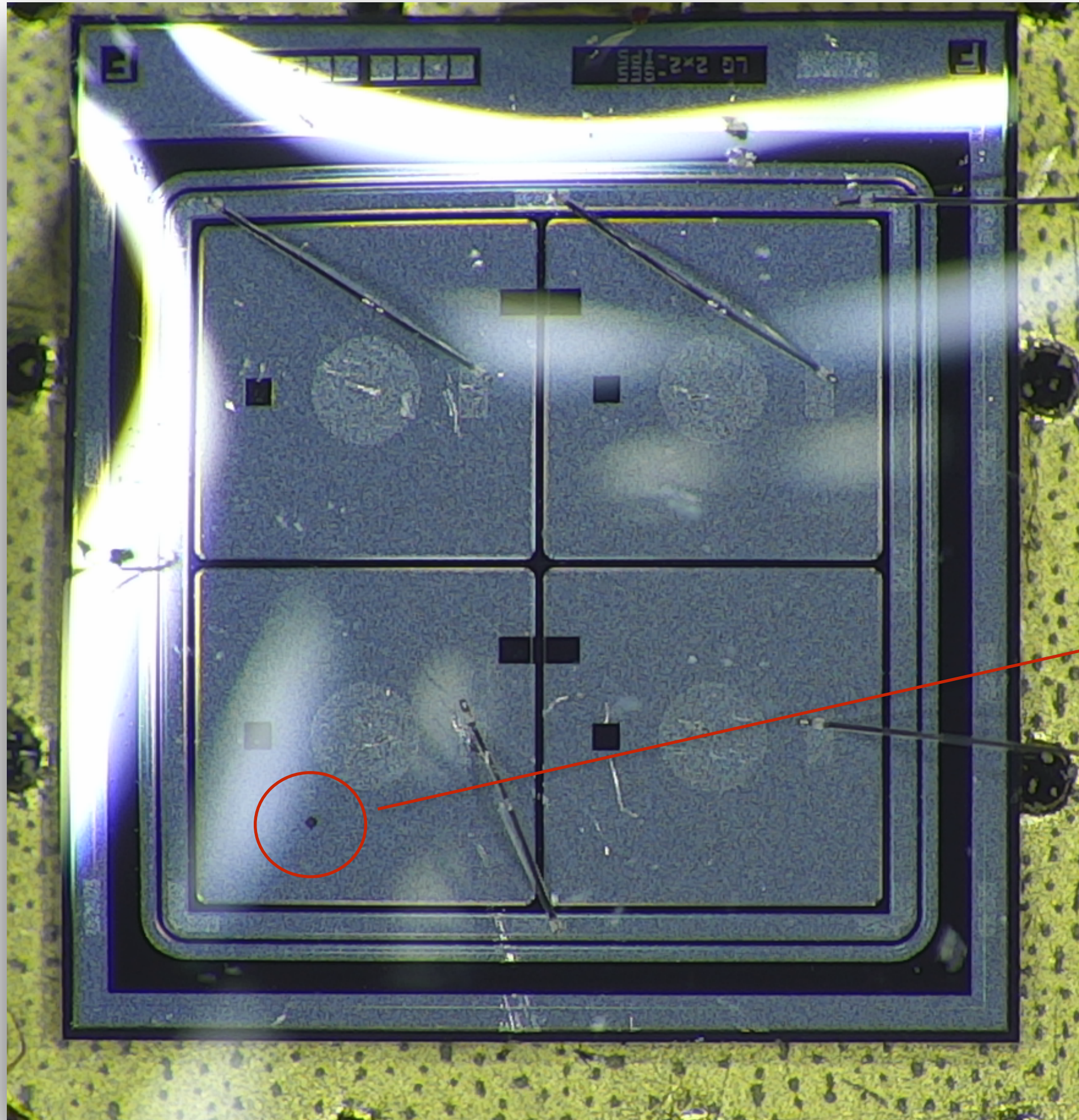
# Context for CMS Endcap Timing Layer (ETL)

- To avoid burnout, LGADs should remain at voltage  $\leq 550$  V (50-55 micron)
  - HPK sensors can deliver  $\sigma < 35$  ps up to  $1e15$  neq/cm<sup>2</sup>, then degrade slowly.
  - FBK sensors can deliver  $\sigma < 35$  ps to end of life ( $1.5e15$ )
- Only  $\sim 10\%$  of sensors will exceed  $1e15$  neq/cm<sup>2</sup>, only in final  $\sim 20\%$  of lifetime
  - Relevant only for few percent of ETL sensor-years
  - For case of FBK sensors: **no performance impact at all!**



# Encapsulated sensors

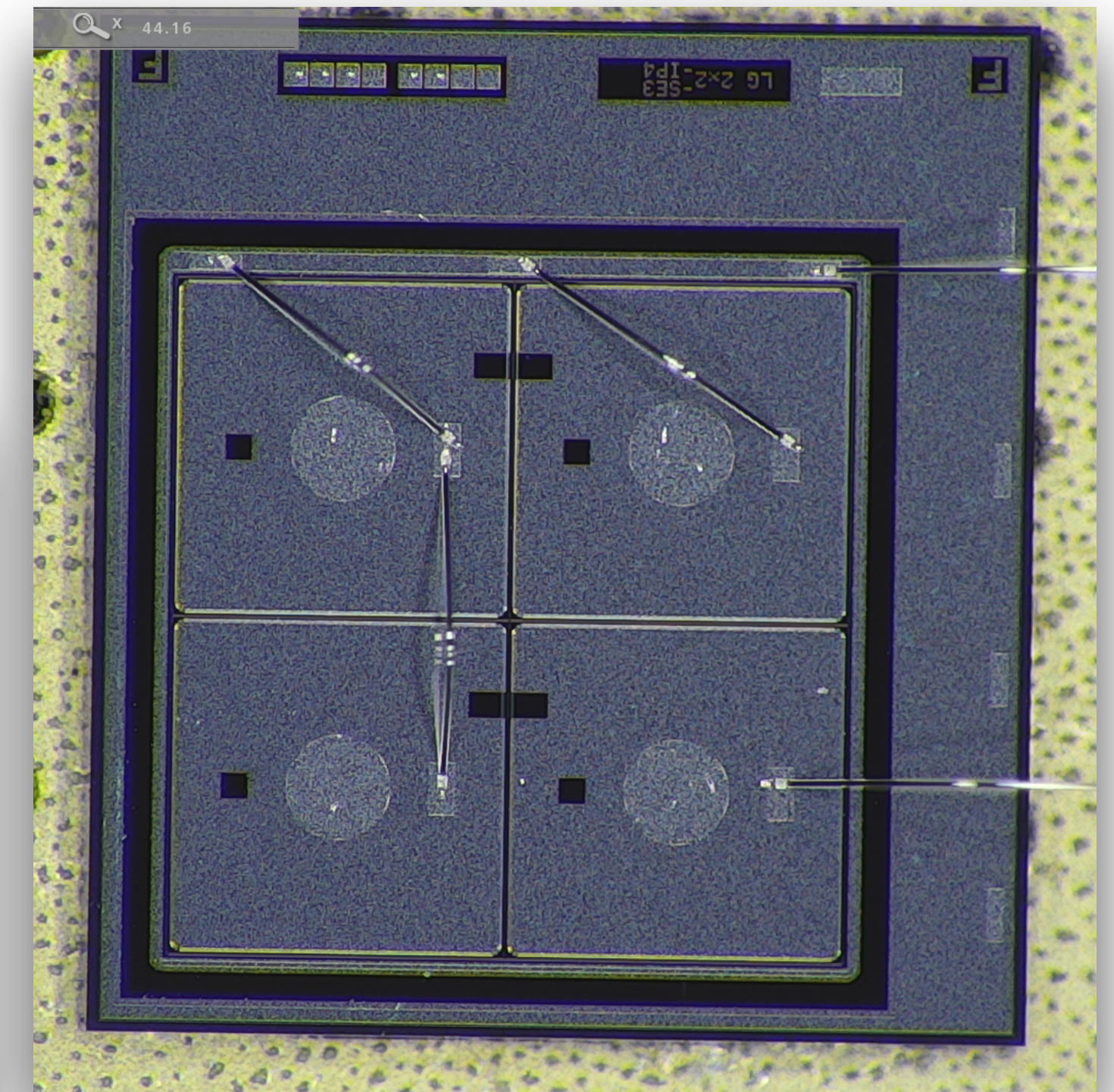
- Two sensors completely covered with wirebond encapsulant (Sylgard 186)
- Crater clearly originates underneath encapsulation. No effect on lifetime or other properties.



# Example death event

- HPK2 split 3 sensor, fluence  $1.5e15$  neq/cm<sup>2</sup>
  - Pre-biased in-situ for 6 hours at 700 V
  - Operated in beam for 2 hours at 500-600 V
  - Destroyed after 2 minutes at 625 V.

HPK2 Split 3 SE3 IP4,  $1.5e15$  neq/cm<sup>2</sup>



(not yet dead)



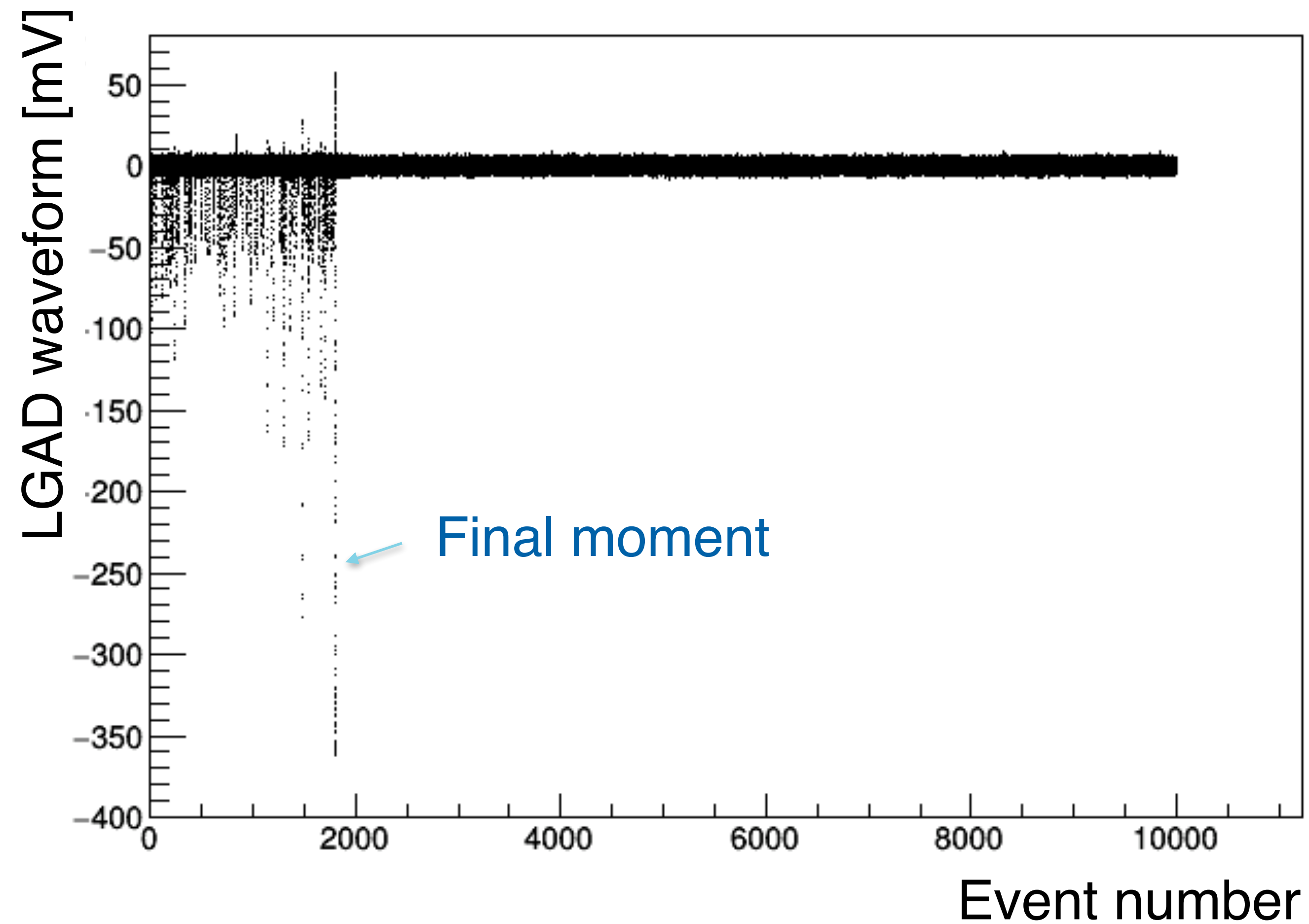
The screenshot shows the GECO2020 software interface. The main window displays a table of system parameters. The table has columns for Custom, ISet, VSet, VMon, Pw, ChStatus, RUp, RDwn, Trip, ImonRange, and ImonRange. The table contains 8 rows of data, with the first and last rows highlighted in red.

Custom	ISet	VSet	VMon	Pw	ChStatus	RUp	RDwn	Trip	ImonRange	ImonRange
00.000	300.00 uA	100.0 V	0.0 V	Off	Disabled	10 Vps	10 Vps	10.0 sec	Hi	0
00.001	31.00 uA	225.0 V	0.0 V	Off	Off	5 Vps	5 Vps	10.0 sec	Low	0
00.002	31.00 uA	1.0 V	0.0 V	Off	Off	1 Vps	5 Vps	10.0 sec	Low	0
00.003	31.00 uA	1.0 V	0.0 V	Off	Off	1 Vps	5 Vps	10.0 sec	Low	0
00.004	31.00 uA	1.0 V	0.0 V	Off	Off	1 Vps	5 Vps	10.0 sec	Low	0
00.005	31.00 uA	1.0 V	0.0 V	Off	Off	1 Vps	5 Vps	10.0 sec	Low	0
00.006	300.00 uA	4400.0 V	0.0 V	Off	Disabled	100 Vps	500 Vps	10.0 sec	Hi	0
00.007	31.00 uA	2800.0 V	0.0 V	Off	Disabled	10 Vps	10 Vps	10.0 sec	Hi	0

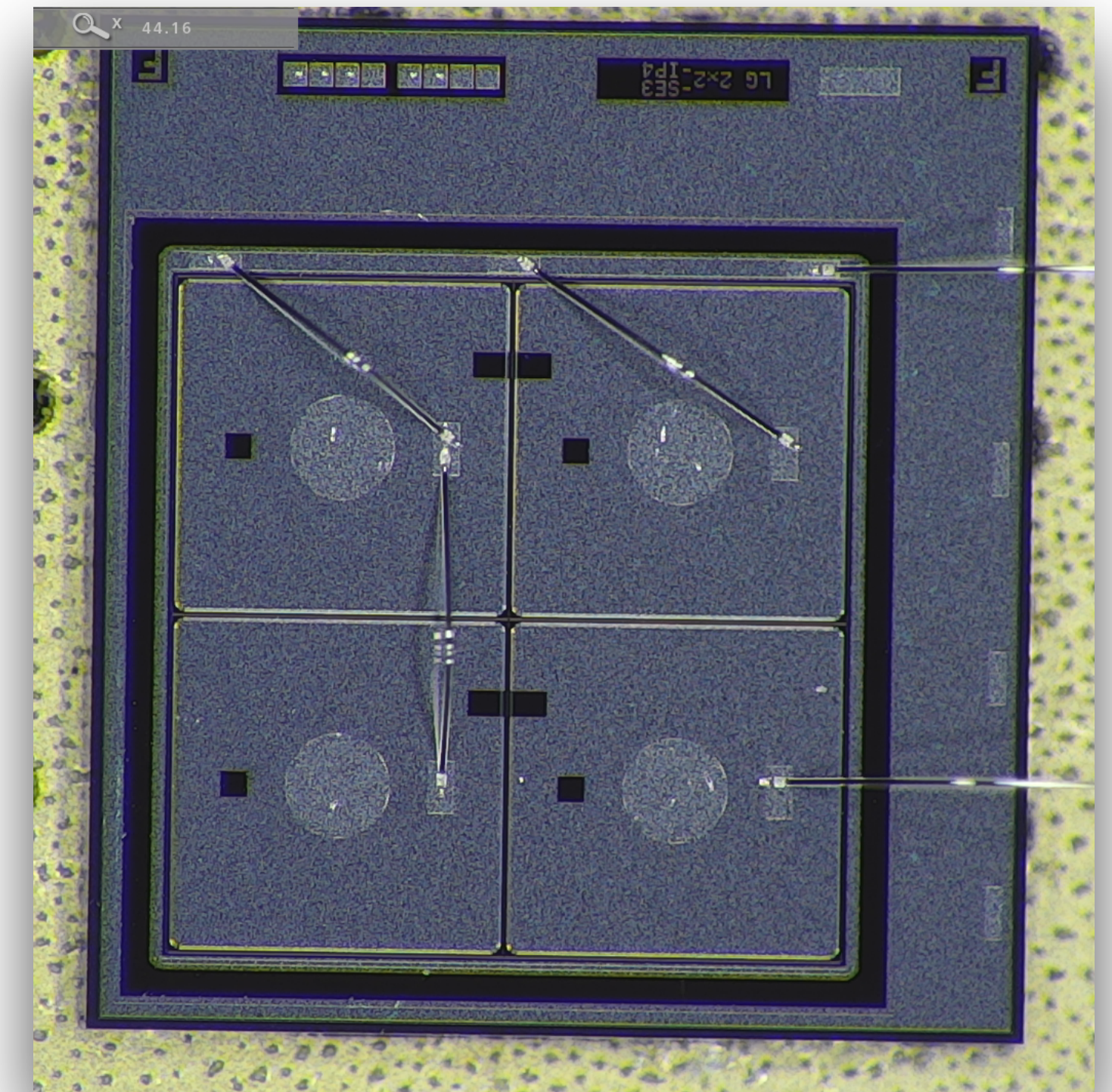
First sign of death: HV short

# Example death event

LGAD waveforms in 10k triggers during 4s spill.



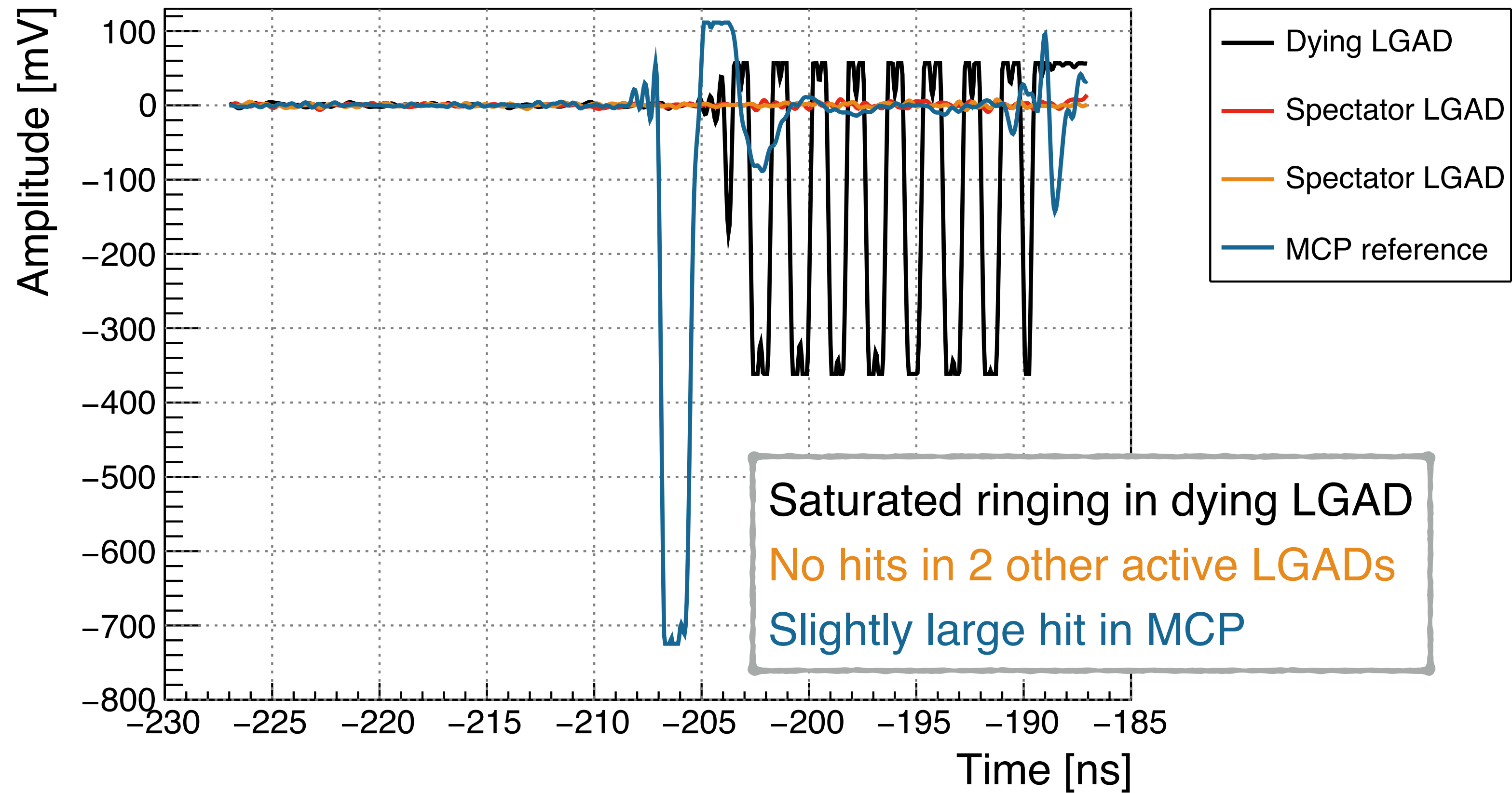
HPK2 Split 3 SE3 IP4,  $1.5e15$  neq/cm<sup>2</sup>



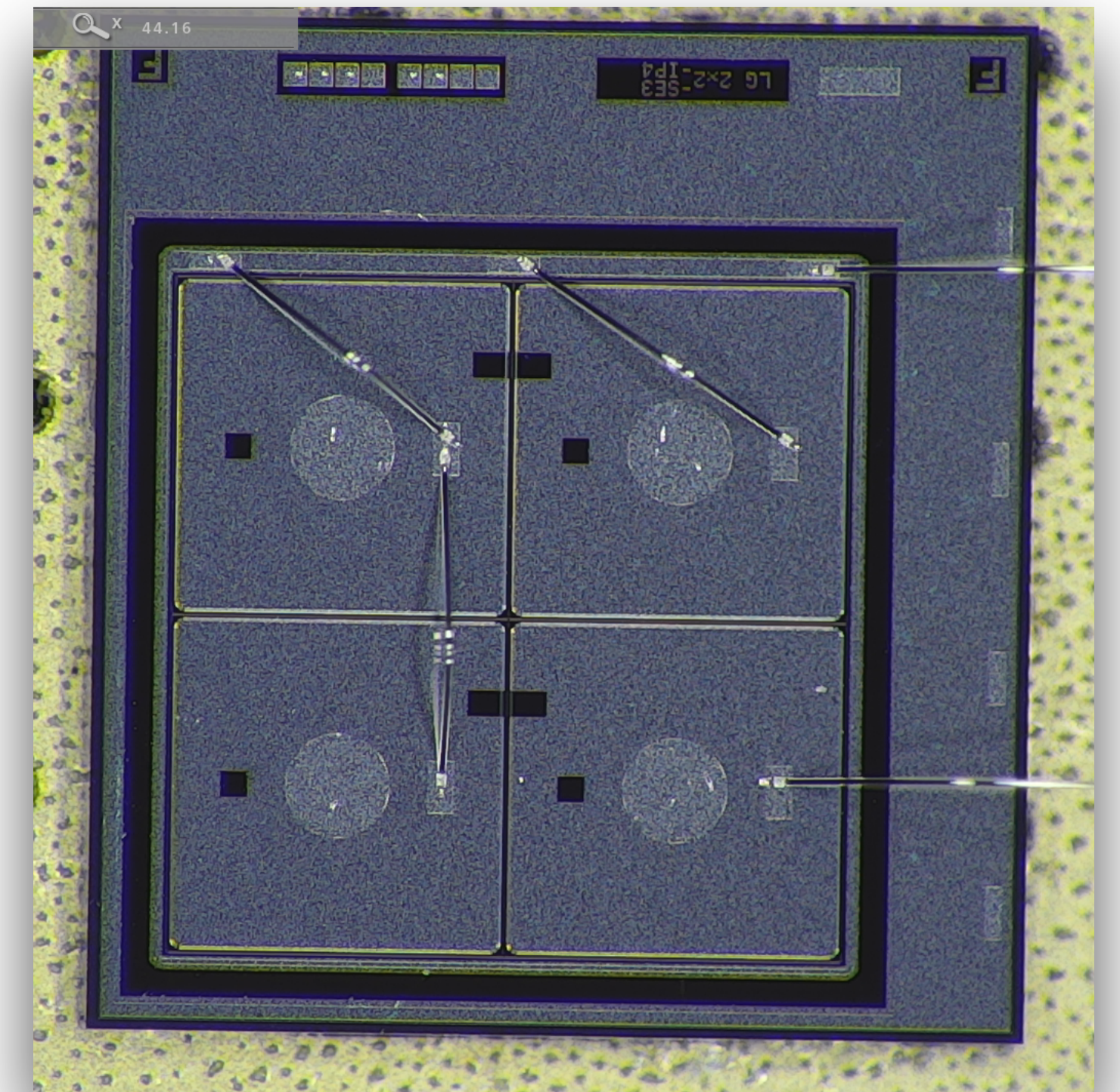
(not yet dead)

# Example death event

Waveforms in fatal event



HPK2 Split 3 SE3 IP4,  $1.5e15$  neq/cm<sup>2</sup>



(not yet dead)

**Death within 1 ns of proton arrival.**